



SGM51613R4A/SGM51613R8A

16-Bit, 1MSPS, 4-Channel/8-Channel Low Power, Serial Interface ADC

GENERAL DESCRIPTION

The SGM51613R4A and SGM51613R8A are 16-bit, 4-channel/8-channel, successive approximation (SAR) analog-to-digital converters (ADCs).

The device is powered by a single source VDD (generally is 5V).

The device can communicate with 1.8V to 5V digital device in which condition the VIO needs to be powered by appropriate voltage accordingly.

The digital interface is compatible to the traditional SPI protocol.

The SGM51613R4A and SGM51613R8A are available in Green TQFN- 4×4-20AL and WLCSP-2.39×2.39-20B packages. It operates over an ambient temperature range of -40°C to +125°C.

APPLICATIONS

Process Control
Power Line Monitoring
Battery-Powered Equipment
Instrumentation

FEATURES

- 16 Bits, 1MSPS SAR ADC
- No Missing Codes
- 4-Channel (SGM51613R4A)/8-Channel (SGM51613R8A) Multiplexer
- Supported Input Types:
 - ♦ Single-Ended
 - ♦ Pseudo Differential (Reference to $1/2V_{REF}$)
 - ♦ Pseudo Differential (Reference to GND)
- Analog Input Range:
0V to V_{REF} with V_{REF} up to V_{DD}
- Supply Voltage Ranges:
 - ♦ Analog Supply: 4.5V to 5.5V
 - ♦ I/O Supply: 1.8V to 5.5V
- Integral Nonlinearity (INL): $\pm 2.5\text{LSB}$ (TYP)
- Total Harmonic Distortion (THD):
 - ♦ -98dB (TYP) at 20kHz for TQFN Package
 - ♦ -97dB (TYP) at 20kHz for WLCSP Package
- Signal-to-Noise + Distortion (SINAD):
91.5dBFS (TYP) at 20kHz
- Power Dissipation
 - ♦ 55mW (TYP) at 1MSPS
 - ♦ 5.4mW (TYP) at 100kSPS
- Standby Current: 1 μ A (TYP)
- Multiple Reference Types
 - ♦ Internal Reference: 4.096V
 - ♦ External Buffered Reference: Up to $V_{DD} - 0.3\text{V}$
 - ♦ External Reference: Up to V_{DD}
- Support Channel Sequencer
- Support Selectable 1-Pole Filter and Busy Indicator
- Internal Temperature Sensor
- SPI-Compatible Serial Interface
- Available in Green TQFN-4×4-20AL and WLCSP-2.39×2.39-20B Packages

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM51613R4A	TQFN-4×4-20AL	-40°C to +125°C	SGM51613R4AXTUH20G/TR	51613R4A XTUH20 XXXXXX	Tape and Reel, 3000
			SGM51613R4AXTUH20SG/TR	51613R4A XTUH20 XXXXXX	Tape and Reel, 500
	WLCSP-2.39×2.39-20B	-40°C to +125°C	SGM51613R4AXG/TR	SGM25I XXXXXX XX#XX	Tape and Reel, 3000
			SGM51613R4AXSG/TR	SGM25I XXXXXX XX#XX	Tape and Reel, 500
SGM51613R8A	TQFN-4×4-20AL	-40°C to +125°C	SGM51613R8AXTUH20G/TR	51613R8A XTUH20 XXXXXX	Tape and Reel, 3000
			SGM51613R8AXTUH20SG/TR	51613R8A XTUH20 XXXXXX	Tape and Reel, 500
	WLCSP-2.39×2.39-20B	-40°C to +125°C	SGM51613R8AXG/TR	SGM1WY XXXXXX XX#XX	Tape and Reel, 3000
			SGM51613R8AXSG/TR	SGM1WY XXXXXX XX#XX	Tape and Reel, 500

MARKING INFORMATION

NOTE: XXXXXX = Date Code, Trace Code and Vendor Code. XX#XX = Coordinate Information and Wafer ID Number.

TQFN-4×4-20AL

XXXXXX

XXXXXX
 Vendor Code
 Trace Code
 Date Code - Year

WLCSP-2.39×2.39-20B

XXXXXX
 Date Code - Year
 Trace Code
 Vendor Code
 XX#XX
 Coordinate Information
 Wafer ID Number ("A" = 01, "B" = 02, ... "Y" = 25)
 Coordinate Information

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Analog Inputs

INx, COM	GND - 0.3V to $V_{DD} + 0.3V$
REF, REFIN	GND - 0.3V to $V_{DD} + 0.3V$

Supply Voltages

V_{DD} , V_{IO} to GND	-0.3V to 6V
V_{DD} to V_{IO}	$\pm 6V$
DIN, CNV, SCLK to GND	-0.3V to $V_{IO} + 0.3V$
SDO to GND	-0.3V to $V_{IO} + 0.3V$
Input Current to Any Pin except Supplies	$\pm 10mA$

Package Thermal Resistance (SGM51613R4A)

TQFN-4x4-20AL, θ_{JA}	35.6°C/W
TQFN-4x4-20AL, θ_{JB}	11.6°C/W
TQFN-4x4-20AL, $\theta_{JC(TOP)}$	26.1°C/W
TQFN-4x4-20AL, $\theta_{JC(BOT)}$	1.7°C/W
WLCSP-2.39x2.39-20B, θ_{JA}	72°C/W
WLCSP-2.39x2.39-20B, θ_{JB}	21.4°C/W
WLCSP-2.39x2.39-20B, θ_{JC}	12°C/W

Package Thermal Resistance (SGM51613R8A)

TQFN-4x4-20AL, θ_{JA}	35.9°C/W
TQFN-4x4-20AL, θ_{JB}	13.1°C/W
TQFN-4x4-20AL, $\theta_{JC(TOP)}$	26.6°C/W
TQFN-4x4-20AL, $\theta_{JC(BOT)}$	1.7°C/W
WLCSP-2.39x2.39-20B, θ_{JA}	72°C/W
WLCSP-2.39x2.39-20B, θ_{JB}	21.4°C/W
WLCSP-2.39x2.39-20B, θ_{JC}	12°C/W

Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility ^{(1) (2)}	
HBM	$\pm 4000V$
CDM	$\pm 1000V$

NOTES:

1. For human body model (HBM), all pins comply with ANSI/ESDA/JEDEC JS-001 specifications.
2. For charged device model (CDM), all pins comply with ANSI/ESDA/JEDEC JS-002 specifications.

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range	-40°C to +125°C
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OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

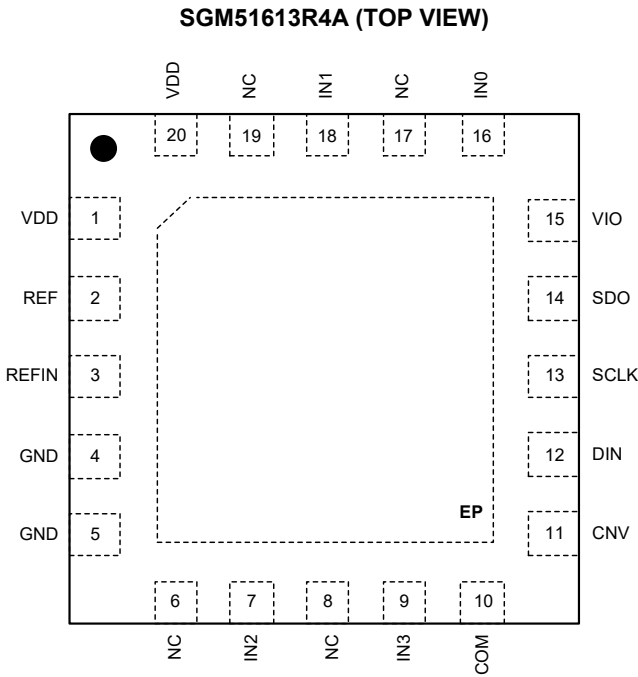
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

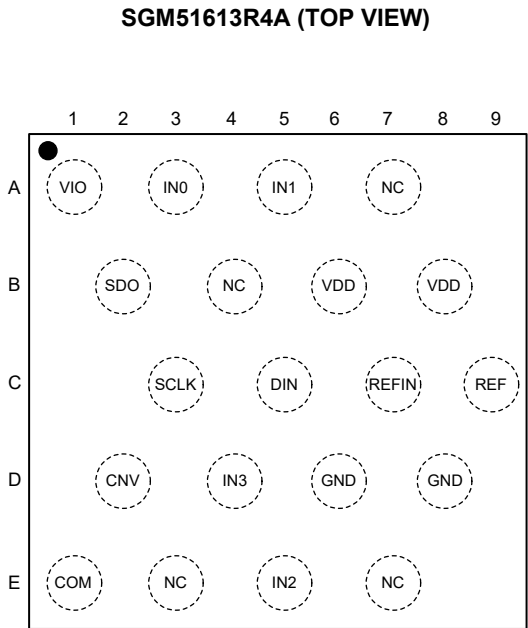
DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

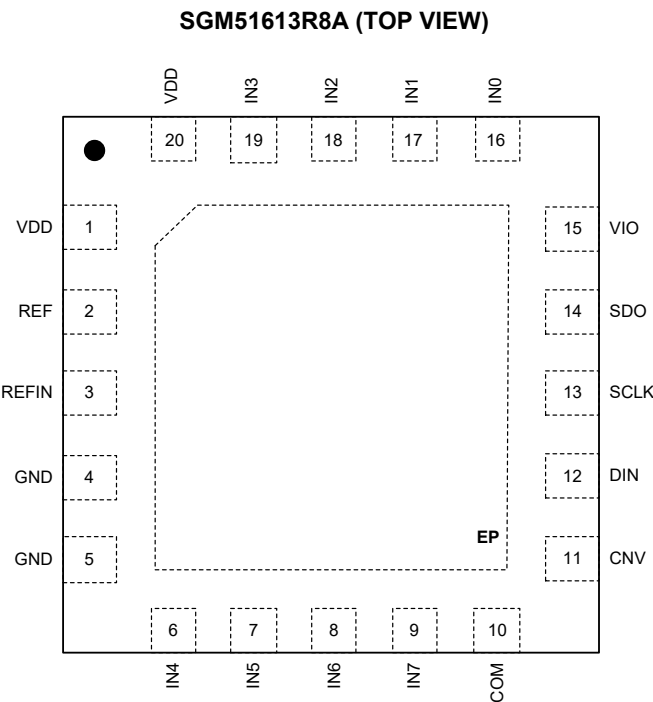
PIN CONFIGURATIONS



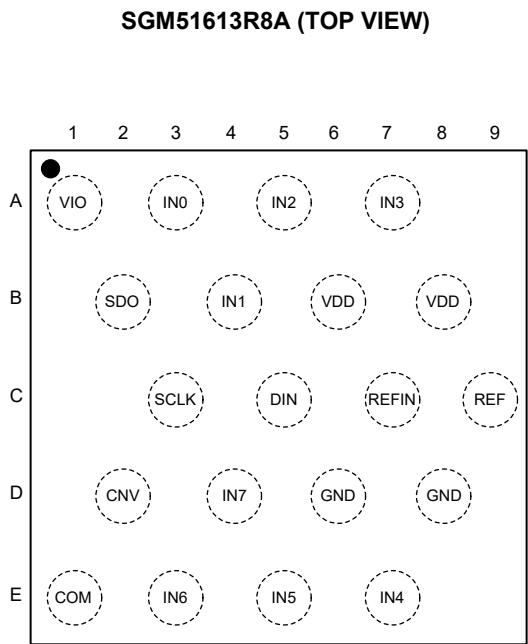
TQFN-4x4-20AL



WLCSP-2.39x2.39-20B



TQFN-4x4-20AL



WLCSP-2.39x2.39-20B

PIN DESCRIPTION

PIN		NAME	TYPE	FUNCTION
TQFN-4×4-20AL	WLCSP-2.39×2.39-20B			
1, 20	B6, B8	VDD	P	Power Supply Pin. The power supply of this pin must be higher than the voltage potential of reference (internal or external). 10μF and 100nF decoupling capacitors should be connected here. The range of VDD is from 4.5V to 5.5V.
2	C9	REF	AI/O	Reference Input/Output Pin. This pin needs to be decoupled by 10μF capacitors to GND and the capacitor should be installed as close to REF as possible. There are three working modes for REF pin. Firstly, when working in the internal reference mode, this pin produces 4.096V and no external reference is needed. Secondly, when the internal reference is disabled and the internal buffer is enabled, REF pin can buffer out the voltage presenting on the REFIN pin. Thirdly, a precise reference can be directly connected to REF pin for the best drift effect.
3	C7	REFIN	AI/O	Internal Reference Output/Reference Buffer Input. It is a multi-function pin. If the internal reference function is selected, a 1μF decoupling capacitor needs to be connected. If the reference buffer input function is selected, an external reference voltage source needs to be connected. The voltage reference available range is from 1V to V _{DD} - 0.3V.
4, 5	D6, D8	GND	P	Power Supply Ground.
6	E7	IN4	AI	Analog Input Pin for Channel 4. (Only for SGM51613R8A)
		NC	—	No Connection. (Only for SGM51613R4A)
7	E5	IN5	AI	Analog Input Pin for Channel 5. (Only for SGM51613R8A)
		IN2		Analog Input Pin for Channel 2. (Only for SGM51613R4A)
8	E3	IN6	AI	Analog Input Pin for Channel 6. (Only for SGM51613R8A)
		NC	—	No Connection. (Only for SGM51613R4A)
9	D4	IN7	AI	Analog Input Pin for Channel 7. (Only for SGM51613R8A)
		IN3		Analog Input Pin for Channel 3. (Only for SGM51613R4A)
10	E1	COM	AI	Common Input Pin. Common voltage reference of analog input channels. All input channels can be referenced to a common mode point of 0V or V _{REF} /2V.
11	D2	CNV	DI	Conversion Input Pin. It is a digital control pin. The rising edge of CNV signal starts the conversion. During conversion, if CNV is held high long enough, the busy indicator is disabled.
12	C5	DIN	DI	Data Input Pin. It is the digital input pin of SPI serial interface.
13	C3	SCLK	DI	Serial Data Clock Input Pin. It is the digital clock input pin of serial interface. The SPI data is locked out is in MSB first format.
14	B2	SDO	DO	Serial Data Output Pin. It is the digital data output pin of serial interface. The SDO will synchronize with the above SCLK and output conversion result. When IN- is connected with GND, the conversion results are straight binary. When IN- is connected with 1/2V _{REF} , the conversion results are two's complement.
15	A1	VIO	P	Input/Output Interface Digital Power Supply Pin. Generally, this pin is powered with the same power source of digital controller.

PIN DESCRIPTION (continued)

PIN		NAME	TYPE	FUNCTION
TQFN- 4×4-20AL	WLCSP- 2.39×2.39-20B			
16	A3	IN0	AI	Analog Input Pin for Channel 0.
17	B4	IN1	AI	Analog Input Pin for Channel 1. (Only for SGM51613R8A)
		NC	—	No Connection. (Only for SGM51613R4A)
18	A5	IN2	AI	Analog Input Pin for Channel 2. (Only for SGM51613R8A)
		IN1	AI	Analog Input Pin for Channel 1. (Only for SGM51613R4A)
19	A7	IN3	AI	Analog Input Pin for Channel 3. (Only for SGM51613R8A)
		NC	—	No Connection. (Only for SGM51613R4A)
Exposed Pad	—	EP	—	Exposed pad should be soldered to PCB board and connected to GND.

NOTE: AI = analog input, AI/O = analog input/output, DI = digital input, DO = digital output, P = power.

ELECTRICAL CHARACTERISTICS

(T_A = -40°C to +125°C, V_{DD} = 5V, V_{REF} = 4.096V to V_{DD}, V_{IO} = 3V, all typical values are measured T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Resolution				16			Bits
Analog Input							
Voltage Range	VIN+ - VIN-	Single-ended mode, or differential with COM (INx- = GND), or differential pairs (INx- = GND)		0		+V _{REF}	V
		Differential with COM (INx- = 1/2V _{REF}), or differential pairs (INx- = 1/2V _{REF})		-V _{REF} /2		+V _{REF} /2	
Absolute Input Voltage		Positive input, unipolar and bipolar modes		-0.1		V _{REF} + 0.1	V
		Negative or COM input, unipolar mode		-0.1		+0.1	
		Negative or COM input, bipolar mode			V _{REF} /2		
Analog Input CMRR		f _{IN} = 250kHz	TQFN package		72		dB
			WLCSP package		59		
Leakage Current at +25°C Input Impedance ⁽¹⁾		Acquisition phase			18		nA
Throughput							
Conversion Rate		Full bandwidth ⁽²⁾				1000	kSPS
		¼ bandwidth ⁽²⁾				250	
Transient Response		Full-scale step, full bandwidth				200	ns
		Full-scale step, ¼ bandwidth				800	
Accuracy							
No Missing Codes					16		Bits
Integral Linearity	INL	TQFN package		-6.5	±2.5	4.5	LSB ⁽³⁾
		WLCSP package		-12	±2.5	12	
Differential Linearity	DNL			-0.999	±0.6	4	LSB
Gain Error ⁽⁴⁾	E _G			-18	±2	18	LSB
Gain Error Match				-8.5	±1	8.5	LSB
Offset Error ⁽⁴⁾	E _O	INCC[2:0] = 00X	TQFN package	-23	±5	14	LSB
			WLCSP package	-20.5	±2	18.5	
		INCC[2:0] = 010	TQFN package	-33	±6	14	
			WLCSP package	-14	±2	29	
		INCC[2:0] = 10X	TQFN package	-15	±2	13	
			WLCSP package	-15.5	±2	15.5	
		INCC[2:0] = 110	TQFN package	-21	±4	11	
			WLCSP package	-16	±2	12	
		INCC[2:0] = 111	TQFN package	-17	±2.5	13	
			WLCSP package	-13.5	±2	13.5	
Offset Error Match		TQFN package		-13	±2	13	LSB
		WLCSP package		-9.5	±2	9.5	
Power Supply Sensitivity		V _{DD} = 5V ± 5%			±1.5		LSB

ELECTRICAL CHARACTERISTICS (continued)

(T_A = -40°C to +125°C, V_{DD} = 5V, V_{REF} = 4.096V to V_{DD}, V_{IO} = 3V, all typical values are measured T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
AC Accuracy						
Signal-to-Noise Ratio	SNR	f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 00X	TQFN package	88.5	92.7	dBFS ⁽⁵⁾
			WLCSP package	86.5	92.3	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 010	TQFN package	88.5	92.7	
			WLCSP package	86.5	92.3	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 10X	TQFN package	88.5	92.7	
			WLCSP package	86	92.3	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 110	TQFN package	88.5	92.7	
			WLCSP package	86	92.3	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 111	TQFN package	88.5	92.7	
			WLCSP package	85.5	92.3	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 00X	TQFN package	85.5	91.5	
			WLCSP package	84.5	91.5	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 010	TQFN package	85.5	91.5	
			WLCSP package	84.5	91.5	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 10X	TQFN package	86.5	91.5	
			WLCSP package	85	91.5	
Signal-to-Noise + Distortion	SINAD	f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 00X	TQFN package	88	91.5	dBFS ⁽⁵⁾
			WLCSP package	85.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 010	TQFN package	88	91.5	
			WLCSP package	85.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 10X	TQFN package	88	91.5	
			WLCSP package	85.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 110	TQFN package	88	91.5	
			WLCSP package	85.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 111	TQFN package	88	91.5	
			WLCSP package	84.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 00X	TQFN package	85	91.0	
			WLCSP package	84	91.0	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 010	TQFN package	85	91.0	
			WLCSP package	84	91.0	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 10X	TQFN package	86	91.0	
			WLCSP package	84	91.0	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 110	TQFN package	86	91.0	
			WLCSP package	84.5	91.0	
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 111	TQFN package	85.5	91.0	
			WLCSP package	84	91.0	

ELECTRICAL CHARACTERISTICS (continued)

(T_A = -40°C to +125°C, V_{DD} = 5V, V_{REF} = 4.096V to V_{DD}, V_{IO} = 3V, all typical values are measured T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
AC Accuracy								
Total Harmonic Distortion	THD	f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 00X, bipolar differential pairs mode	TQFN package		-98	-91	dB	
			WLCSP package		-97	-85		
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 010, bipolar mode	TQFN package		-98	-89		
			WLCSP package		-97	-84		
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 10X, unipolar differential pairs mode	TQFN package		-98	-91		
			WLCSP package		-97	-85		
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 110, unipolar to COM mode	TQFN package		-98	-89		
			WLCSP package		-97	-84		
		f _{IN} = 20kHz, V _{REF} = 5V, INCC[2:0] = 111, unipolar mode	TQFN package		-98	-89		
			WLCSP package		-97	-85		
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 00X, bipolar differential pairs mode	TQFN package		-100	-91		
			WLCSP package		-100	-85		
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 010, bipolar mode	TQFN package		-100	-91		
			WLCSP package		-100	-85		
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 10X, unipolar differential pairs mode	TQFN package		-100	-89		
			WLCSP package		-100	-84		
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 110, unipolar to COM mode	TQFN package		-100	-89		
			WLCSP package		-100	-84		
		f _{IN} = 20kHz, V _{REF} = 4.096V, INCC[2:0] = 111, unipolar mode	TQFN package		-100	-89		
			WLCSP package		-100	-85		
Spurious Free Dynamic Range	SFDR	f _{IN} = 20kHz			101		dB	
Channel-to-Channel Crosstalk		f _{IN} = 100kHz on adjacent channel(s)	TQFN package		-109		dB	
			WLCSP package		-85			
Sampling Dynamics								
-3dB Input Bandwidth		Full bandwidth			21		MHz	
		¼ bandwidth			5.5			
Internal Reference								
REF Output Voltage		At -40°C to +125°C		4.081	4.096	4.111	V	
REFIN Output Voltage ⁽⁶⁾		At +25°C			4.096		V	
REF Output Current					±300		µA	
Temperature Drift					±10		ppm/°C	
Line Regulation		V _{DD} = 5V ± 5%			±15		ppm/V	

ELECTRICAL CHARACTERISTICS (continued)

(T_A = -40°C to +125°C, V_{DD} = 5V, V_{REF} = 4.096V to V_{DD}, V_{IO} = 3V, all typical values are measured T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Internal Reference							
Long Term Drift		1000 hours			160		ppm
Turn-On Settling Time		C _{REF} = 10μF			5		ms
External Reference							
Voltage Range		REF input		0.5		V _{DD}	V
		REFIN input (buffered)		1	4.096	V _{DD} - 0.3	
Current Drain		1MSPS, V _{REF} = 5V			300		μA
Temperature Sensor							
Output Voltage ⁽⁷⁾		At +25°C			620		mV
Temperature Sensitivity					2		mV/°C
Digital Inputs							
Low Input Voltage	V _{IL}					0.23 × V _{IO}	V
High Input Voltage	V _{IH}			0.7 × V _{IO}			V
Low Input Current	I _{IL}			-1		1	μA
High Input Current	I _{IH}			-1		1	μA
Digital Outputs							
Data Format ⁽⁸⁾							
Pipeline Delay ⁽⁹⁾							
Low Output Voltage	V _{OL}	I _{SINK} = +500μA				0.4	V
High Output Voltage	V _{OH}	I _{SOURCE} = -500μA		V _{IO} - 0.3			V
Power Requirements							
Analog Supply Voltage	V _{DD}	Specified performance		4.5	5	5.5	V
Digital I/O Supply Voltage	V _{IO}	Specified performance		1.8	3	V _{DD}	V
Standby Current ^{(10) (11)}		V _{DD} and V _{IO} = 5V, at +25°C			1		μA
Power Dissipation		V _{DD} = 5V	100kSPS throughput		5.4		mW
			1MSPS throughput		55	95	
			1MSPS throughput with internal reference		65	100	
Temperature Range							
Specified Performance		T _{MIN} to T _{MAX}		-40		125	°C

NOTES:

1. Refer to the Input Structure section for more details.
2. The bandwidth depends on the configuration register settings.
3. LSB = Least Significant Bit. 1LSB = 76.3μV in the 5V input range.
4. These include the full temperature range variation, but exclude the error contribution from the reference.
5. All those parameters are tested with an input signal at -0.5dB for full-scale, unless otherwise specified. The specifications expressed in dBFS are tested with a -0.5dB signal and are recalculated to a full-scale input signal.
6. It is the output from the internal band gap.
7. The output voltage is internal and present on a dedicated multiplexer input.
8. Serial 16-bit straight binary in unipolar mode. Serial 16-bit two's complement in bipolar mode.
9. After the conversion is completed, the conversion results are provided immediately.
10. All digital inputs are forced to V_{IO} or GND as required.
11. In the acquisition phase.

TIMING CHARACTERISTICS

($V_{DD} = 4.5V$ to $5.5V$, $V_{REF} = 4.096V$ to V_{DD} , $V_{IO} = 1.8V$ to V_{DD} , $T_A = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted.)⁽¹⁾

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Conversion Time: CNV Rising Edge to Data Available	t_{CONV}				830	ns
Acquisition Time	t_{ACQ}		170			ns
Time between Conversions	t_{CYC}		1			μs
CNV Pulse Width	t_1		10			ns
Data Write/Read during Conversion	t_{DATA}				500	ns
SCLK Period ⁽²⁾	t_2		$t_6 + 2$			ns
SCLK Low Time	t_3	V_{IO} above 3V	7			ns
		V_{IO} above 1.8V	8			
SCLK High Time	t_4	V_{IO} above 3V	7			ns
		V_{IO} above 1.8V	8			
SCLK Falling Edge to Data Remains Valid	t_5		4			ns
SCLK Falling Edge to Data Valid Delay	t_6	V_{IO} above 4.5V			11	ns
		V_{IO} above 3V			12	
		V_{IO} above 2.7V			13	
		V_{IO} above 2.3V			14	
		V_{IO} above 1.8V			15	
CNV Low to SDO D15 MSB Valid	t_7	V_{IO} above 4.5V			11	ns
		V_{IO} above 3V			12	
		V_{IO} above 2.7V			13	
		V_{IO} above 2.3V			14	
		V_{IO} above 1.8V			16	
CNV High or Last SCLK Falling Edge to SDO High Impedance	t_8				20	ns
CNV Low to SCLK Rising Edge	t_9		10			ns
Last SCLK Falling Edge to CNV Rising Edge Delay	t_{10}		55			ns
DIN Valid Setup Time from SCLK Rising Edge	t_{11}		5			ns
DIN Valid Hold Time from SCLK Rising Edge	t_{12}		5			ns

NOTES:

- See Figure 2 and Figure 3.
- t_2 must be greater than $t_3 + t_4$.
- The C_{LOAD} of measuring digital timing is 50pF.

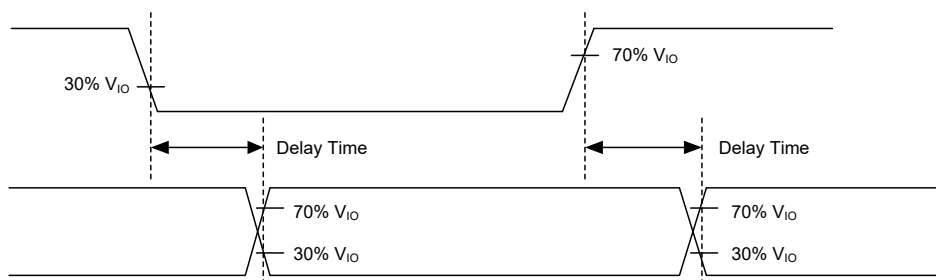
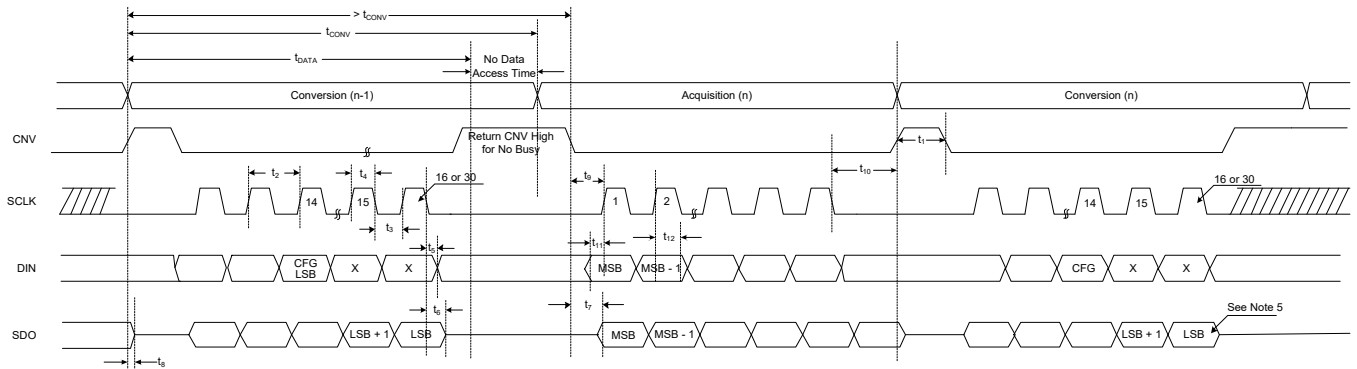


Figure 1. Voltage Levels of Timing Measurement

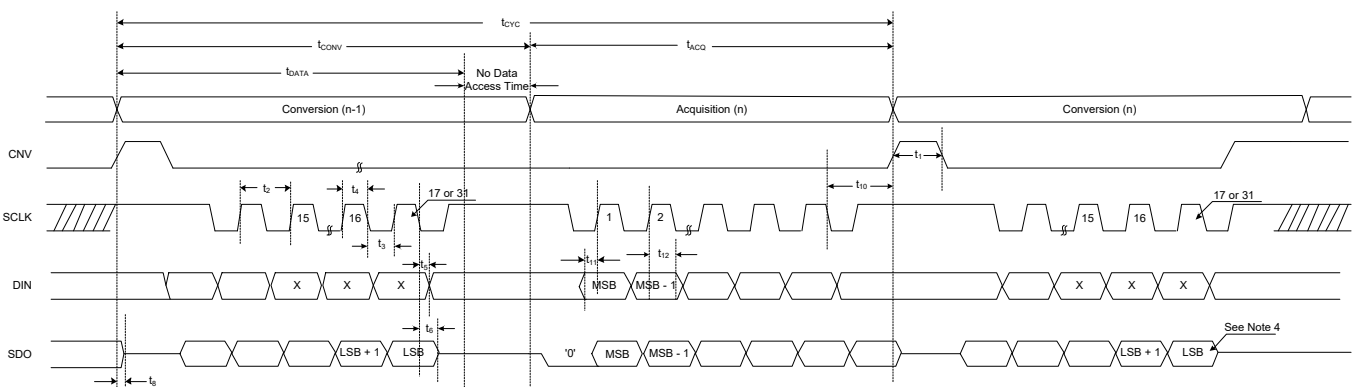
TIMING DIAGRAMS



NOTES:

1. No data access time is a transition time between t_{CONV} and t_{DATA} . During this time, there should not be any read or write operation.
2. The CPOL (clock polarity) bit controls the steady state value of the clock when no data is being transferred.
3. Register Write Operation: The first 14-SCLK rising edges update the configuration of register (CFG). It is in MSB first format. It means that the MSB of the register (Bit[13]) is written at the first SCLK rising edge.
4. Conversion Result Read Operation: The MSB of ADC conversion result is locked out by the falling edge of CNV, and the following ADC data bit is locked out by the subsequent 15-SCLK falling edges. The 16-SCLK falling edge sets the SDO to high impedance status.
5. If CFG readback is disabled, at least 16 SCLKs are needed for the conversion code reading. If CFG readback is enabled, at least 30 SCLKs are needed for both conversion result code and configuration register reading.

Figure 2. Serial Interface Timing without a Busy Indicator (CPOL = 0)



NOTES:

1. No data access time is a transition time between t_{CONV} and t_{DATA} . During this time, there should not be any read or write operation.
2. The CPOL (clock polarity) bit controls the steady state value of the clock when no data is being transferred.
3. Register Write Operation: The first 14-SCLK rising edges update the configuration of register (CFG). It is in MSB first format. It means that the MSB of the register (Bit[13]) is written at the first SCLK rising edge.
4. Conversion Result Read Operation: The BUSY indicate bit '0' on SDO pin is shifted out automatically after the conversion is completed. The subsequent data bit is MSB of ADC conversion result which is locked out by the falling edge of SCLK. To shift out all 16-bit ADC codes, it will take total 16 falling edges of SCLK. And the 17-SCLK falling edge sets the SDO to high impedance status. If CFG readback is disabled, at least 17 SCLK falling edges are needed for the conversion code reading. If CFG readback is enabled, at least 31 SCLK falling edges are needed for both conversion result code and configuration register reading.

Figure 3. Serial Interface Timing with a Busy Indicator (CPOL = 1)

TIMING DIAGRAMS (continued)

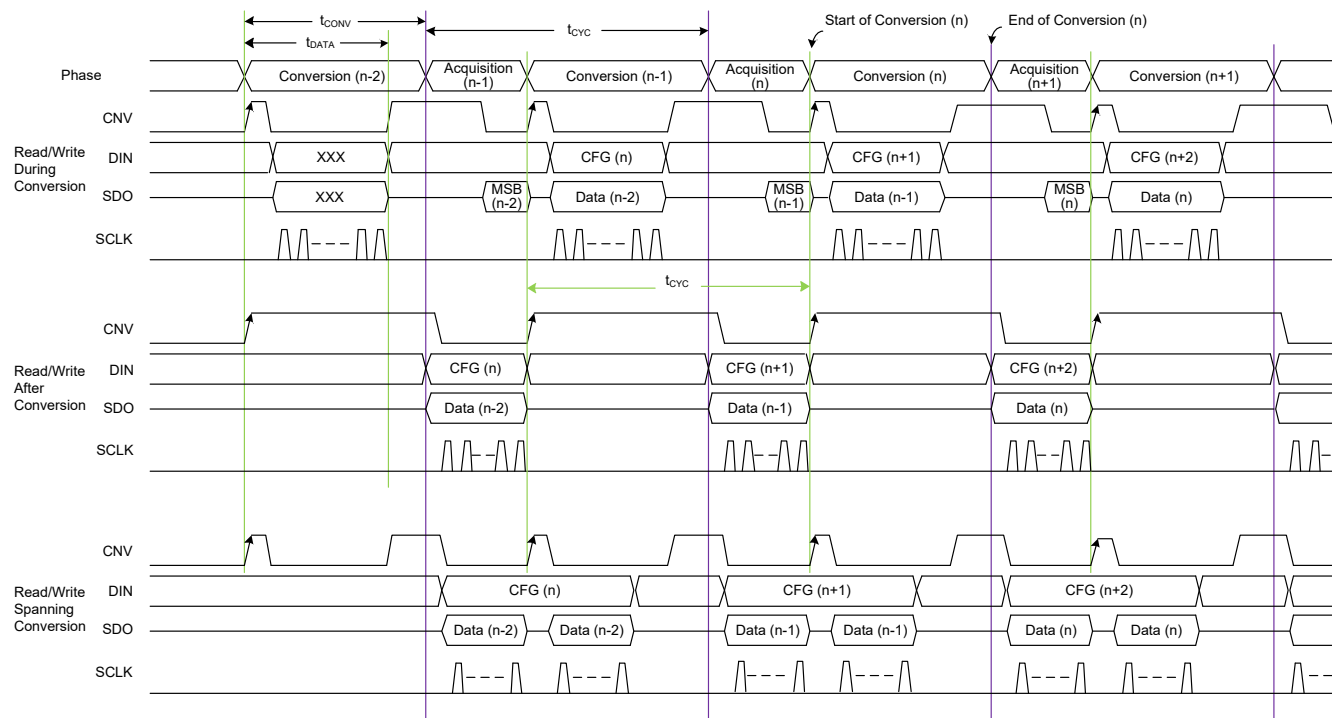


Figure 4. Reading and Writing Sequence without a Busy Indicator (CPOL = 0)

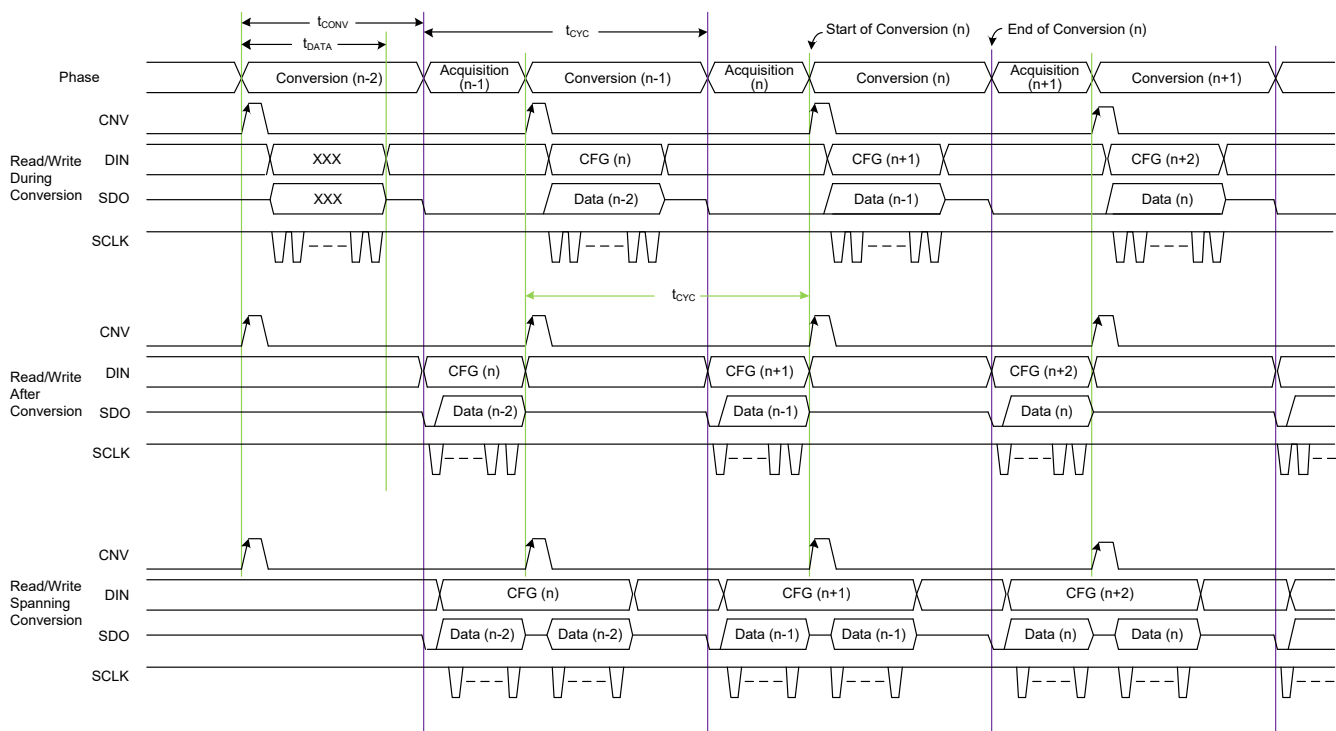


Figure 5. Reading and Writing Sequence with a Busy Indicator (CPOL = 1)

OPERATING TIMING SEQUENCE

The SGM51613R4A and SGM51613R8A can be operated in 3 kinds of timing sequence modes. These modes are not configured by software or hardware. The only difference is that reading/writing time slot is put at different operation timing window.

Reading/Writing during Conversion

As shown in Figure 4 and Figure 5, if the SGM51613R4A and SGM51613R8A are operated in reading (writing) during conversion (cycle #N) mode, the current reading ADC code is the conversion of previous cycle (cycle #N-1). If writing the CFG during conversion (for example, cycle #N+1), the configuration will be effective in next cycle (cycle #N+2).

The transition time is the time between the t_{CONV} and t_{DATA} . It is not recommended to do any operation during this time, because the device does update conversion result during this time. Any operation may cause data corrupted.

The time t_{DATA} is the maximum time which is available for last round conversion result reading.

It is recommended that the host controller should finish reading operation within time of t_{DATA} , in other words, the host controller should read the ADC code as soon as possible, whatever the sampling speed is adopted by the system.

At least a 50MHz SPI SCLK speed is recommended in this mode.

If CNV keeps high at the moment of conversion finishing, the device will not output BUSY indicator signal. Otherwise, the device will output BUSY indicator signal as the first output bit on SDO pin.

Reading/Writing after Conversion

As shown in Figure 4 and Figure 5, if the SGM51613R4A and SGM51613R8A are operated in reading (writing) after conversion mode (cycle #N), the reading ADC code is the conversion of last cycle (cycle #N-1). If writing the CFG after conversion (for example, cycle #N+1), the configuration will be effective in next cycle (cycle #N+2).

In this operating mode, all reading (writing) process is issued during acquisition time. As in high speed sampling mode, the minimum acquisition time $t_{ACQ(MIN)}$ is a short time slot, reading (writing) process is compressed to a short time. It is recommended that reading (writing) after conversion mode is used for low speed sampling application.

If CNV keeps high at the moment of conversion finishing, the device will not output BUSY indicator signal. Otherwise, the device will output BUSY indicator signal as the first output bit on SDO pin.

Reading/Writing Spanning Conversion

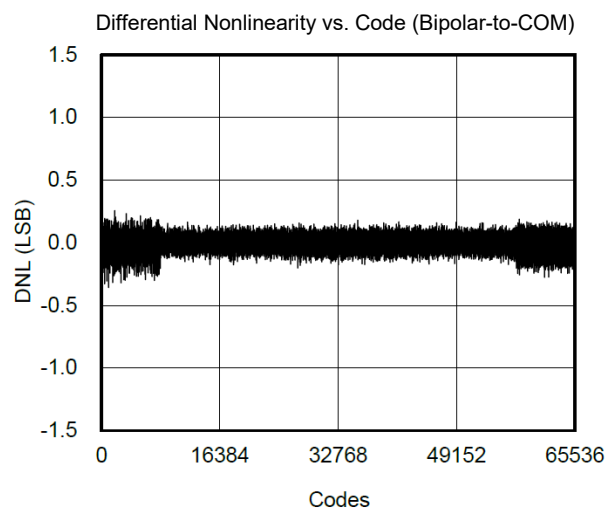
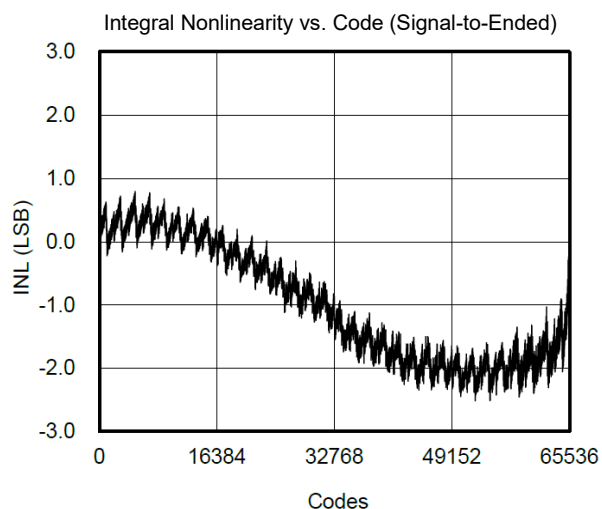
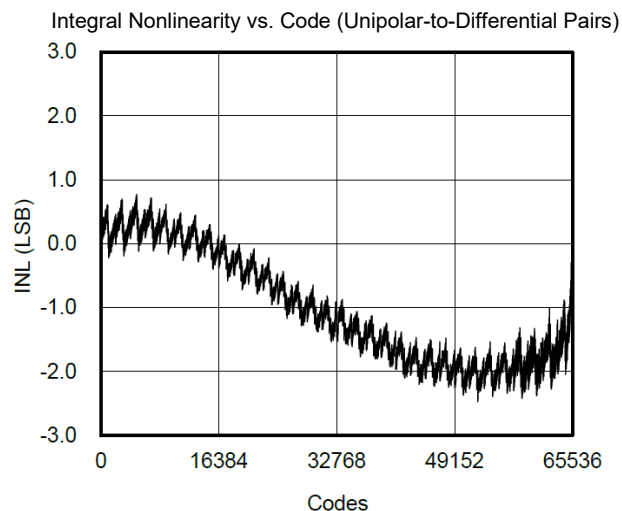
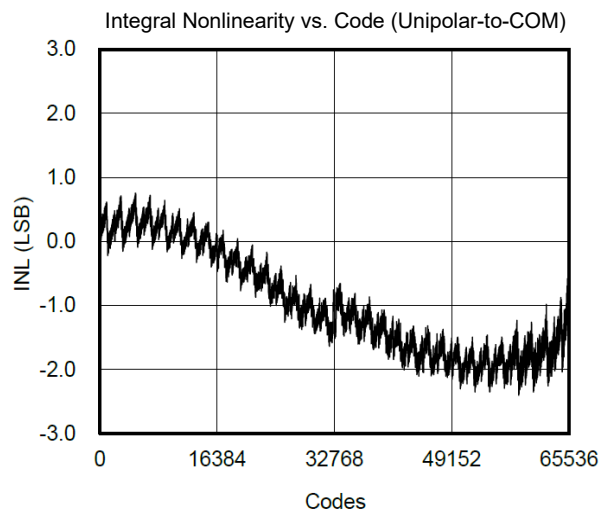
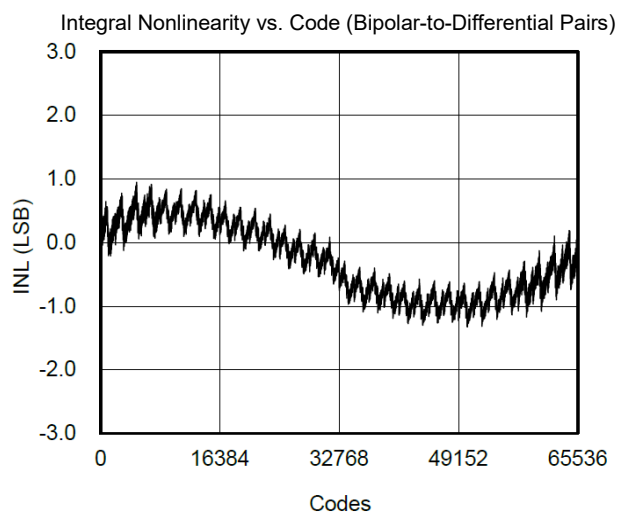
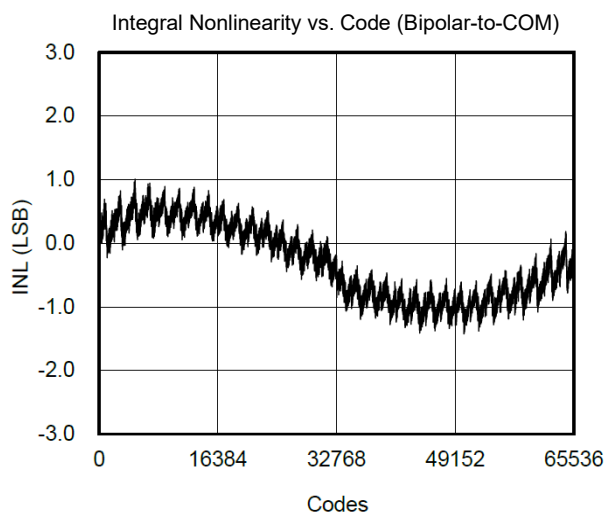
As shown in Figure 4 and Figure 5, if the SGM51613R4A and SGM51613R8A are operated in reading (writing) spanning conversion mode (cycle #N), the current reading ADC code is the conversion of previous cycle (cycle #N-1). If writing the CFG in the current acquisition and conversion cycle (for example, cycle #N+1), the configuration will be effective in next acquisition and conversion cycle (cycle #N+2).

In this mode, the host controller can perform data accessing two times of operation sections to complete one ADC code reading. For these two times of operation sections, it is not necessarily to have to be combined by '8 SCLKs + 8 SCLKs', and it can be any combination, such as '4 SCLKs + 12 SCLKs' or '5 SCLKs + 11 SCLKs'.

There are restrictions for these two times of operation sections. The first operation section must be finished within the acquisition time. The second operation section must be finished within t_{DATA} to prevent data corruption, which is similar to reading/writing during conversion. Data accessing is not allowed when CNV is high. For the maximum throughput, the allocation of SCLKs needs to be carefully considered. Because $t_{ACQ(MIN)}$ is a restricted parameter, it is a better choice to send out less SCLKs in first round and more in second round to achieve maximum sampling rate.

TYPICAL PERFORMANCE CHARACTERISTICS

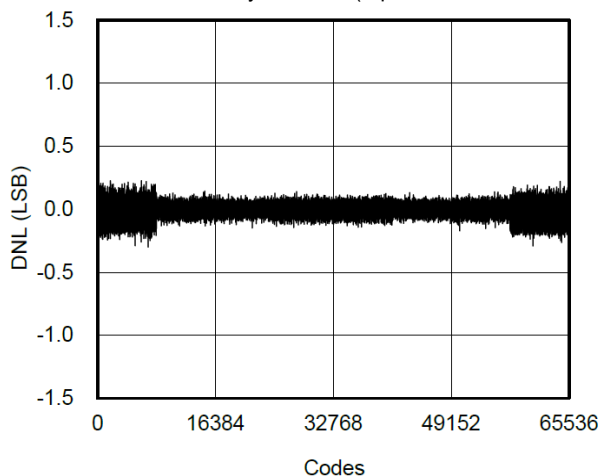
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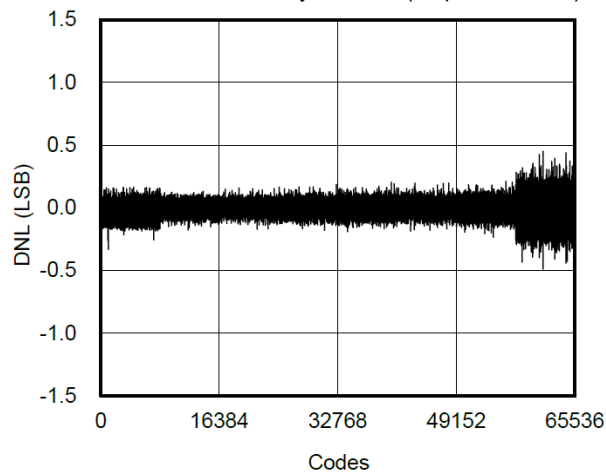
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

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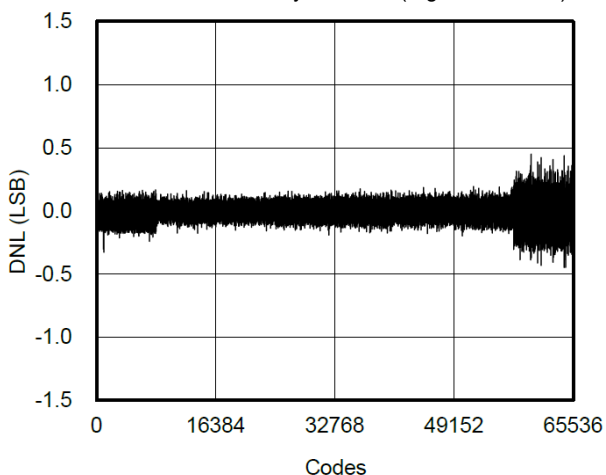
Differential Nonlinearity vs. Code (Bipolar-to-Differential Pairs)



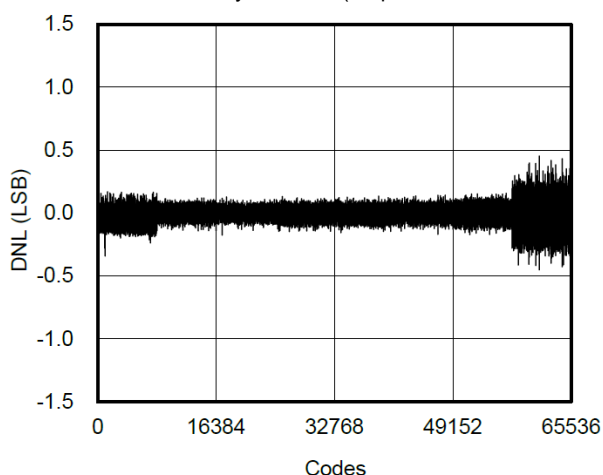
Differential Nonlinearity vs. Code (Unipolar-to-COM)



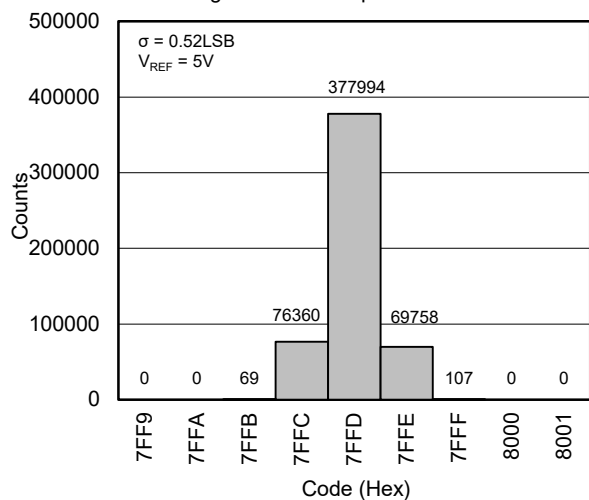
Differential Nonlinearity vs. Code (Signal-to-Ended)



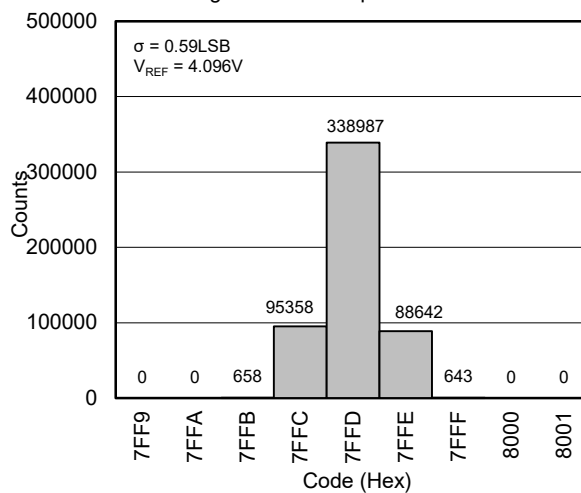
Differential Nonlinearity vs. Code (Unipolar-to-Differential Pairs)



Histogram of a DC Input at Code Center

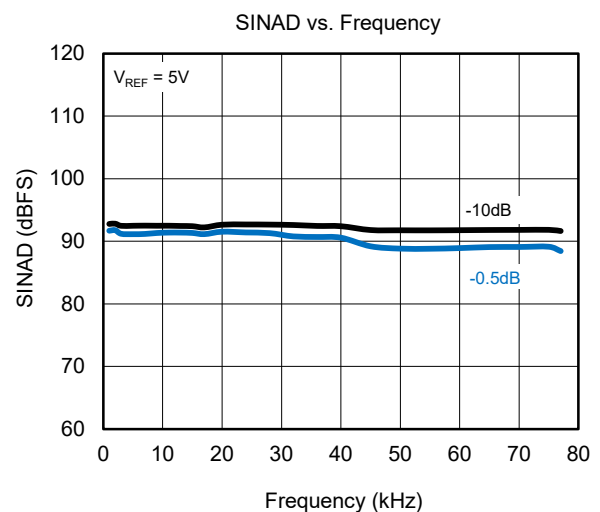
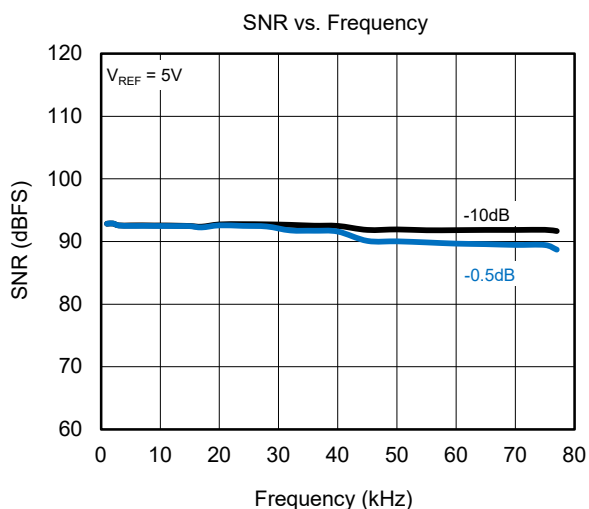
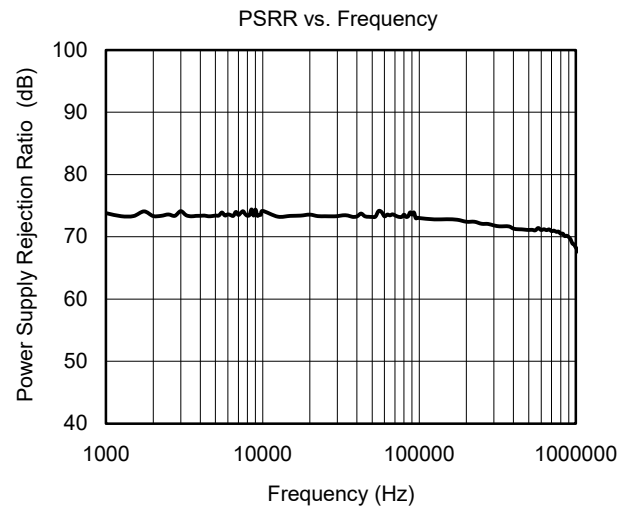
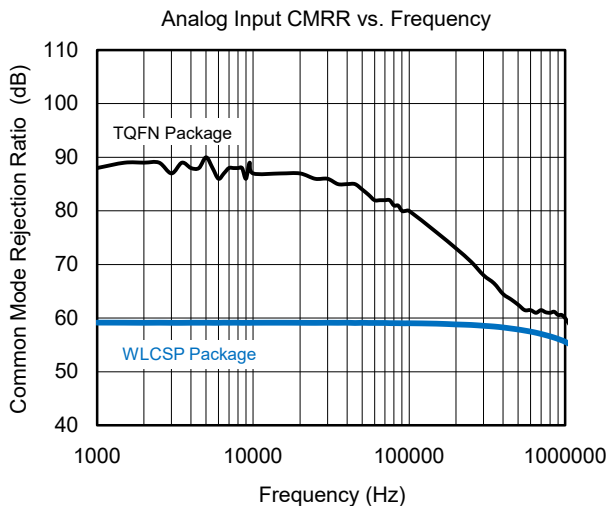
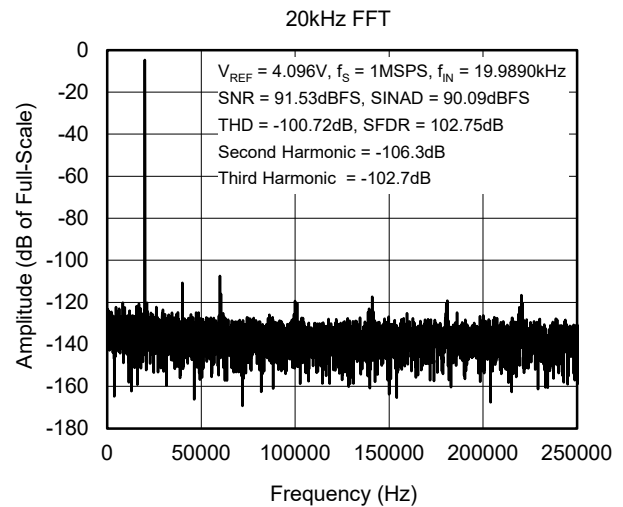
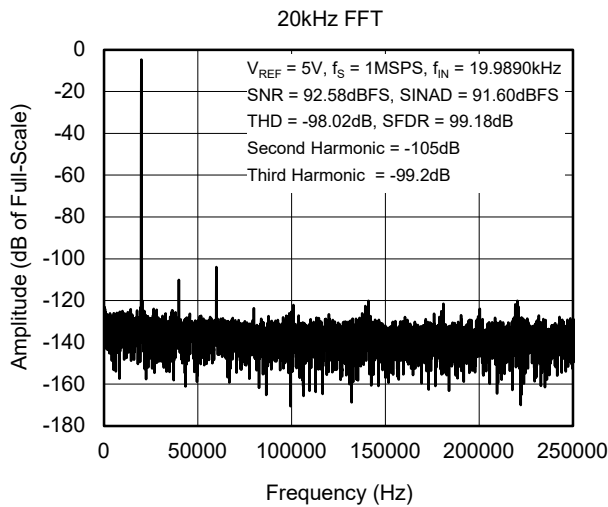


Histogram of a DC Input at Code Center



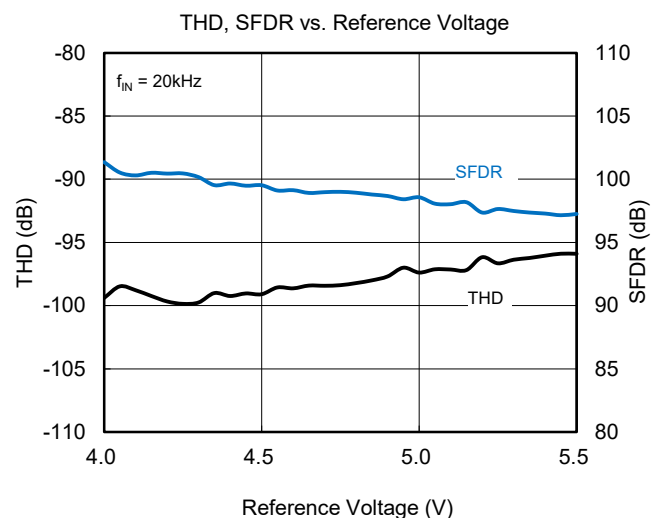
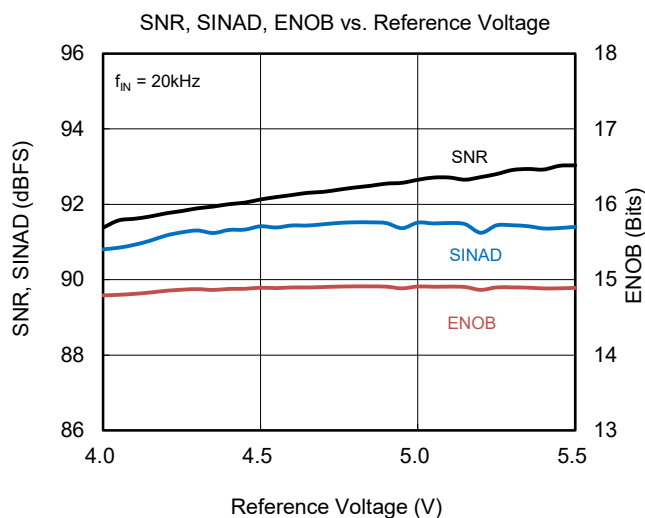
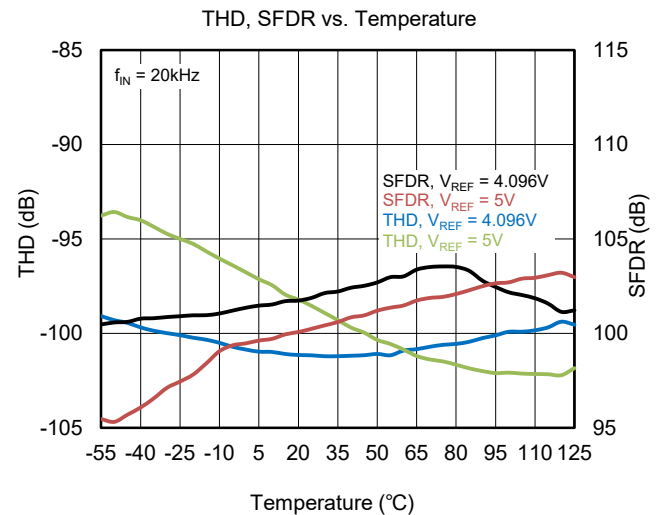
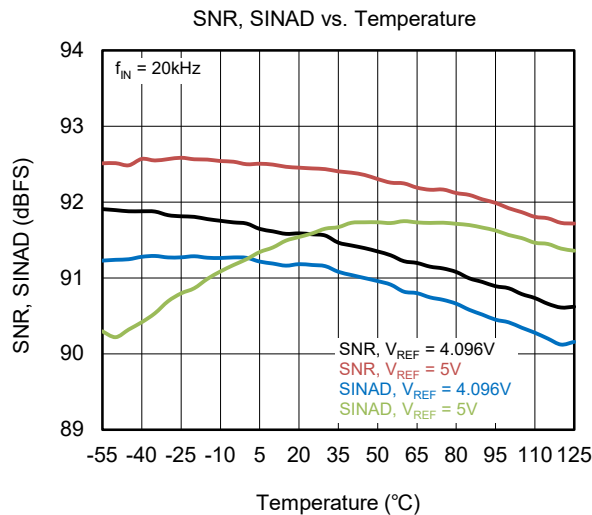
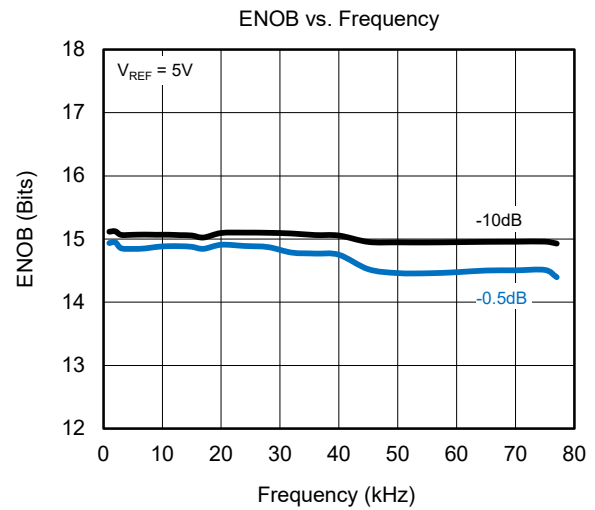
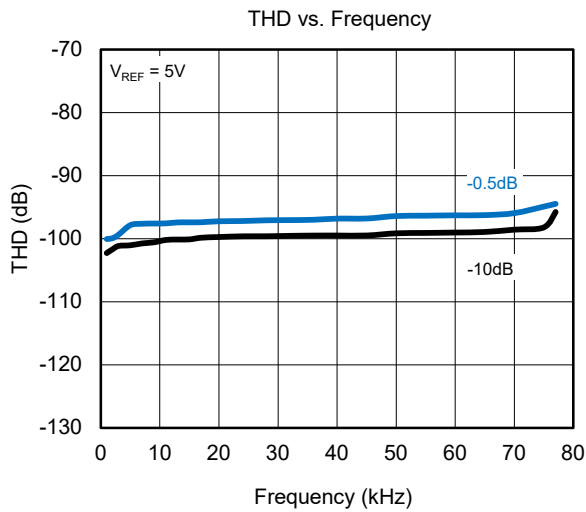
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{DD} = 5V$, $V_{REF} = 5V$, $V_{IO} = V_{DD}$, unless otherwise noted.



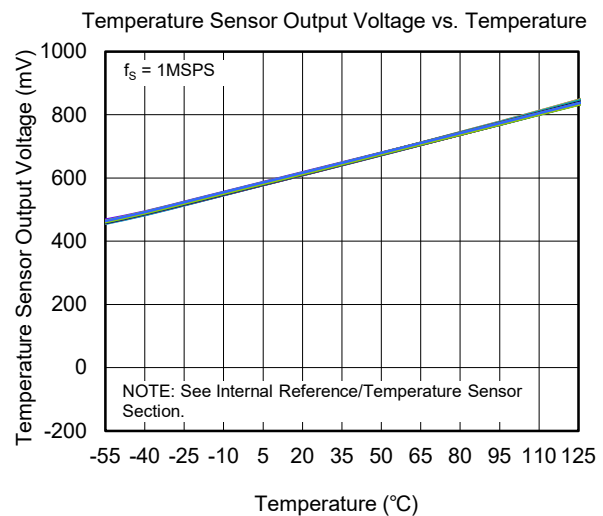
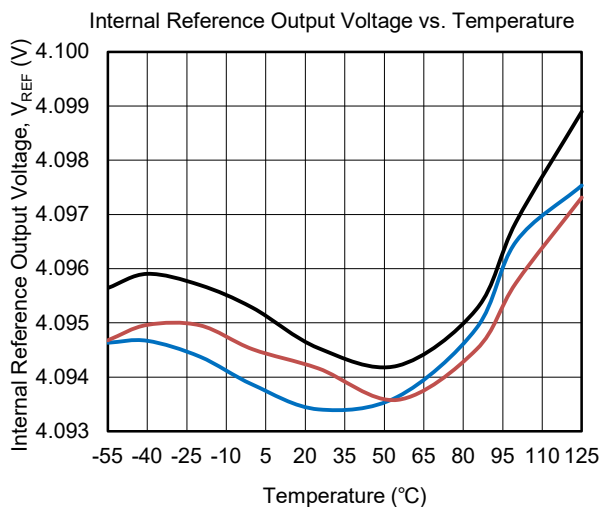
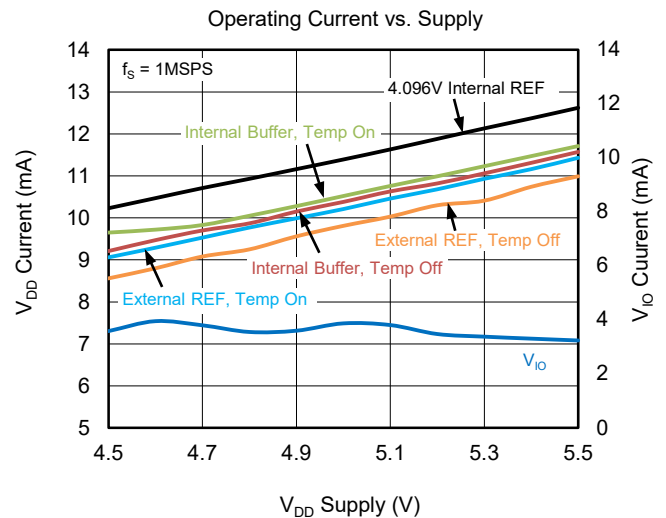
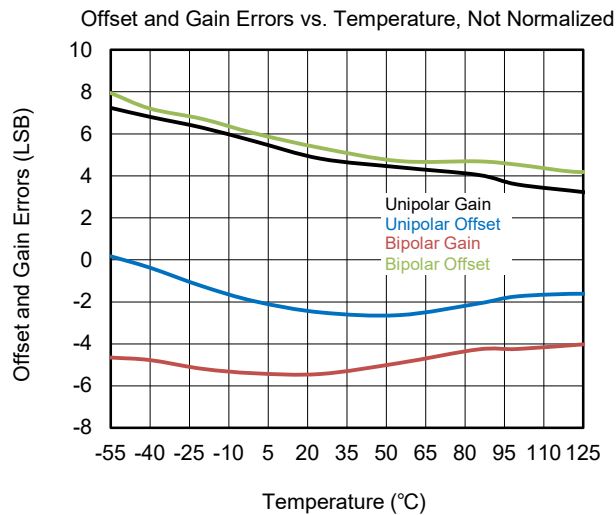
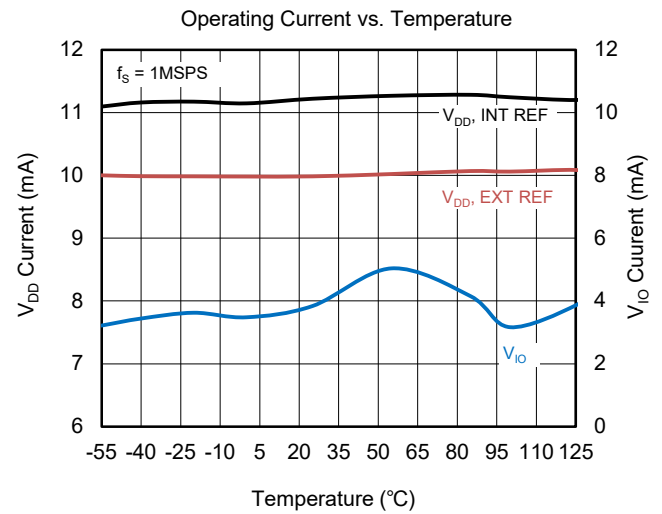
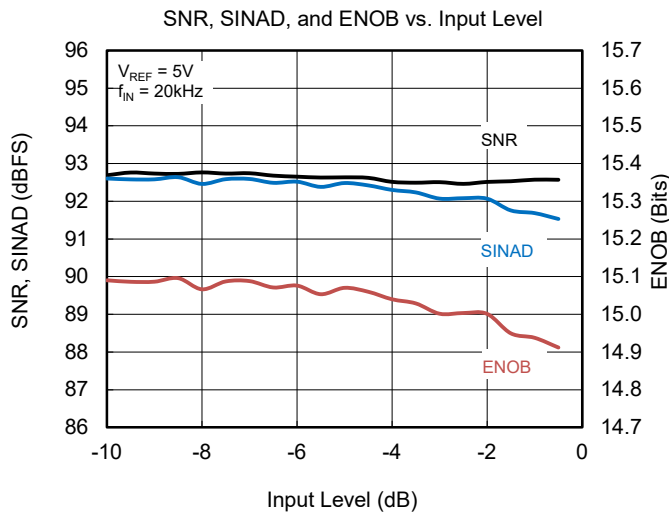
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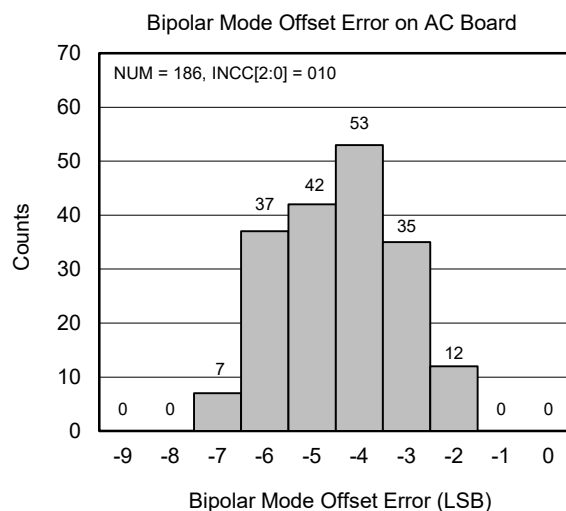
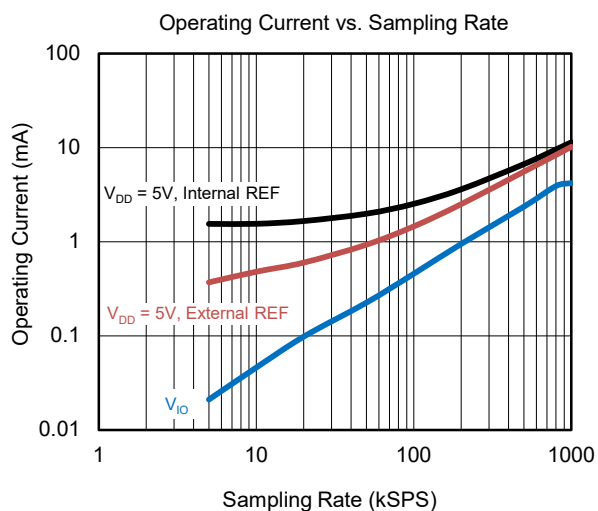
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

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TYPICAL PERFORMANCE CHARACTERISTICS (continued)

$V_{DD} = 5V$, $V_{REF} = 5V$, $V_{IO} = V_{DD}$, unless otherwise noted.



FUNCTIONAL BLOCK DIAGRAM

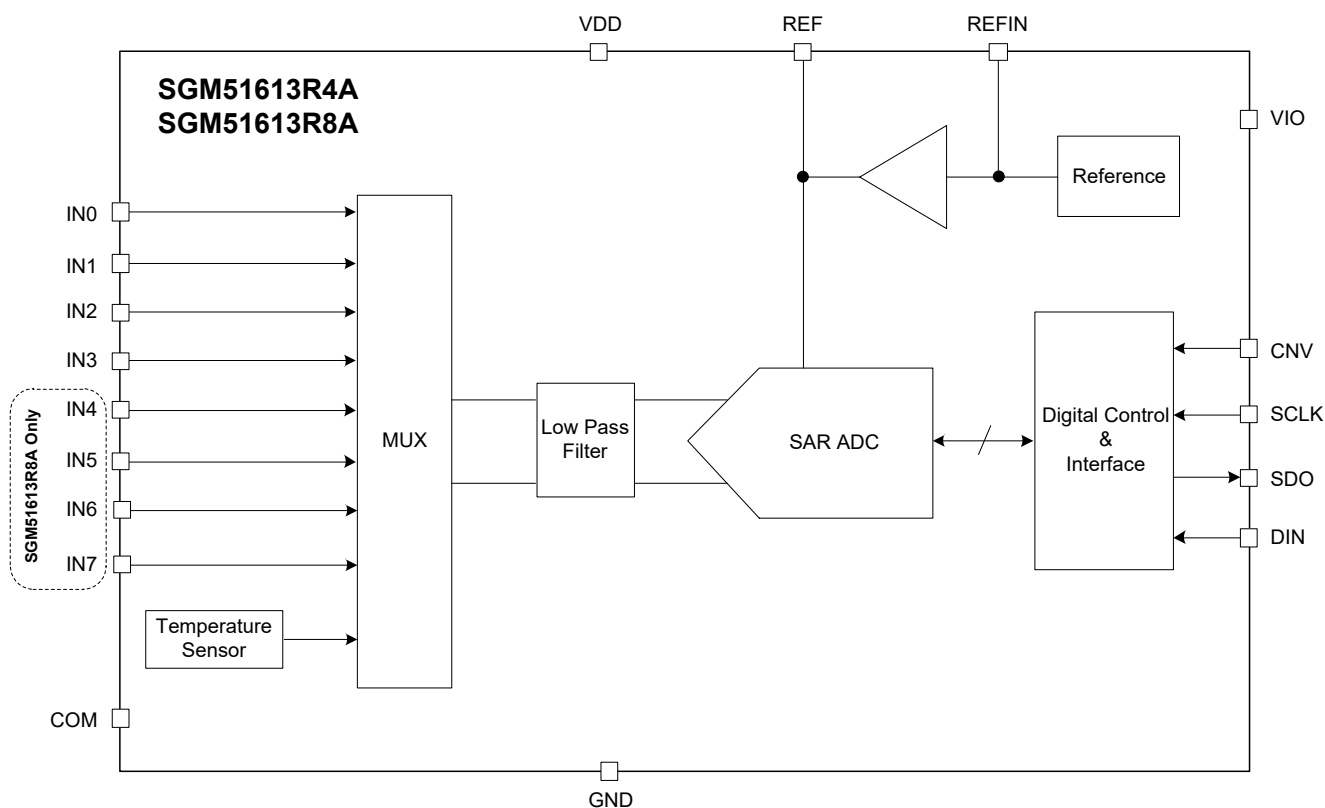


Figure 6. Block Diagram

DETAILED DESCRIPTION

The SGM51613R4A and SGM51613R8A are 4-channel/8-channel 16-bit successive approximation ADCs, which are based on the switched capacitor array architecture.

The SGM51613R4A and SGM51613R8A have an on-chip internal oscillator which is used to the clock source of internal conversion. The SCLK is not required for the conversion process.

Transfer Functions

The SGM51613R4A and SGM51613R8A support 5 kinds of input modes, which include single-ended, pseudo differential to COM (referenced to GND or $1/2V_{REF}$) and pseudo differential pairs (referenced to GND or $1/2V_{REF}$). For the first mode, the inputs are configured as single-ended, all eight channels are referenced to GND, and the data output is a

straight binary. For the second and third modes, the inputs are configured as pseudo differential to a common reference (COM). If the COM is connected to GND, then the data output is a straight binary, and if the COM is connected to $V_{REF}/2$, then the data output is two's complement. For the fourth and fifth modes, the inputs are configured as pseudo differential pairs of two adjacent channels. If the $INx-$ is connected to GND, then the data output is a straight binary, if the $INx-$ is connected to $V_{REF}/2$, then the data output is two's complement.

Figure 7 shows the ideal transfer characteristic. Table 1 and Table 2 show the correspondence between the input voltage range and the output code.

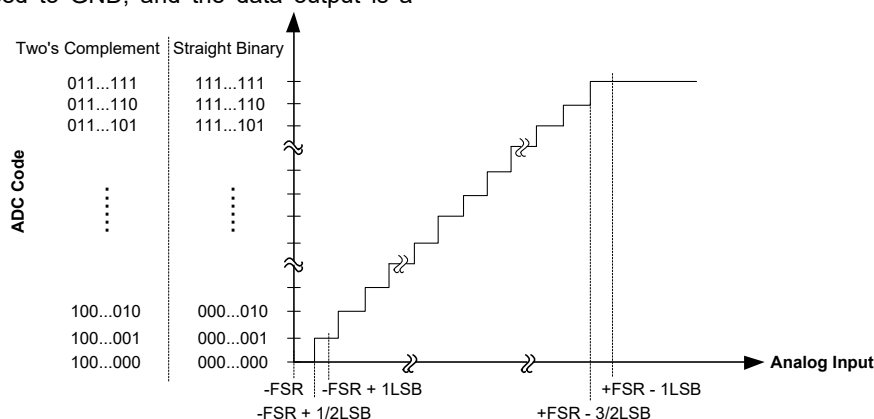


Figure 7. ADC Ideal Transfer Function

Table 1. Theoretical Input Voltages and Output Codes of Unipolar Mode

Description	Digital Output Code (Straight Binary Hex)	Analog Input of Unipolar Mode $V_{REF} = 4.096V^{(1)}$	Analog Input of Unipolar Mode $V_{REF} = 5.0V^{(1)}$
FSR - 1LSB	0xFFFF	4.095938V	4.999923V
Mid-scale + 1LSB	0x8001	2.048063V	2.500076V
Mid-scale	0x8000	2.048V	2.5V
Mid-scale - 1LSB	0x7FFF	2.047938V	2.499923V
-FSR + 1LSB	0x0001	62.5μV	76.29μV
-FSR	0x0000	0V	0V

NOTE: 1. Unipolar Mode: With COM or $INx- = 0V$ or all INx referenced to GND.

Table 2. Theoretical Input Voltages and Output Codes of Bipolar Mode

Description	Digital Output Code (Two's Complement Hex)	Analog Input of Bipolar Mode $V_{REF} = 4.096V^{(1)}$	Analog Input of Bipolar Mode $V_{REF} = 5.0V^{(1)}$
FSR - 1LSB	0x7FFF	2.047938V	2.499923V
Mid-scale + 1LSB	0x0001	62.5μV	76.29μV
Mid-scale	0x0000	0V	0V
Mid-scale - 1LSB	0xFFFF	-62.5μV	-76.29μV
-FSR + 1LSB	0x8001	-2.047938V	-2.499923V
-FSR	0x8000	-2.048V	-2.5V

NOTE: 1. Bipolar Mode: With COM or $INx- = V_{REF}/2$.

DETAILED DESCRIPTION (continued)

Input Configurations

The SGM51613R4A and SGM51613R8A can be configured as single-ended input or pseudo differential input. In both modes, the positive pin input range is 0V to V_{REF} , and the negative input pin must be GND or $V_{REF}/2$. The selectable configurations are shown in the following 4 conditions:

Configuration A: CFG[12:10] = 111, all 4 channels/8 channels are single-ended input and referenced to GND pin. In this case, each input channel VIN+ is channel0+ to channel3+ (SGM51613R4A)/channel7+ (SGM51613R8A), each input channel VIN- is GND.

Configuration B: CFG[12:10] = 010, all 4 channels/8 channels are pseudo differential to COM pin, and COM pin is connected to $V_{REF}/2$. CFG[12:10] = 110, all 4 channels/8 channels are pseudo differential to COM pin, and COM pin is connected to GND. In this case, each input channel channelx+ is INx+, and the COM pin is INx-.

Configuration C: CFG[12:10] = 00x, two adjacent channels of all inputs are combined as differential pairs, and the channelx- is referenced to $V_{REF}/2$. CFG[12:10] = 10X, two adjacent channels of all inputs are combined as differential pairs, and the channelx- is referenced to GND. In this case,

which channel of these adjacent pairs is channelx+ or channelx- is defined by CFG[9:7]. For example, if CFG[9:7] = 000, the positive pin (channel0+) is IN0, and the negative pin (channel0-) is IN1, vice versa.

Configuration D: The chip supports dynamic combined configuration.

More details of input configuration please refer to Figure 8.

Input Structure

The input signal applied to INx and COM must be limited in the range that is listed in Electrical Characteristics table.

The SGM51613R4A and SGM51613R8A are capacitor array SAR ADCs. During the sampling period, there is an input current flowing into the ADC. The peak input current depends on sampling rate, reference voltage, input voltage and signal source impedance.

A driver amplifier is usually suggested to buffer the signal source. It makes the analog input source to charge the equivalent input capacitor (44pF) to a 16-bit accuracy level in the acquisition time. When the input capacitor is fully charged, no further current flows. An equivalent input circuit is shown in Figure 9.

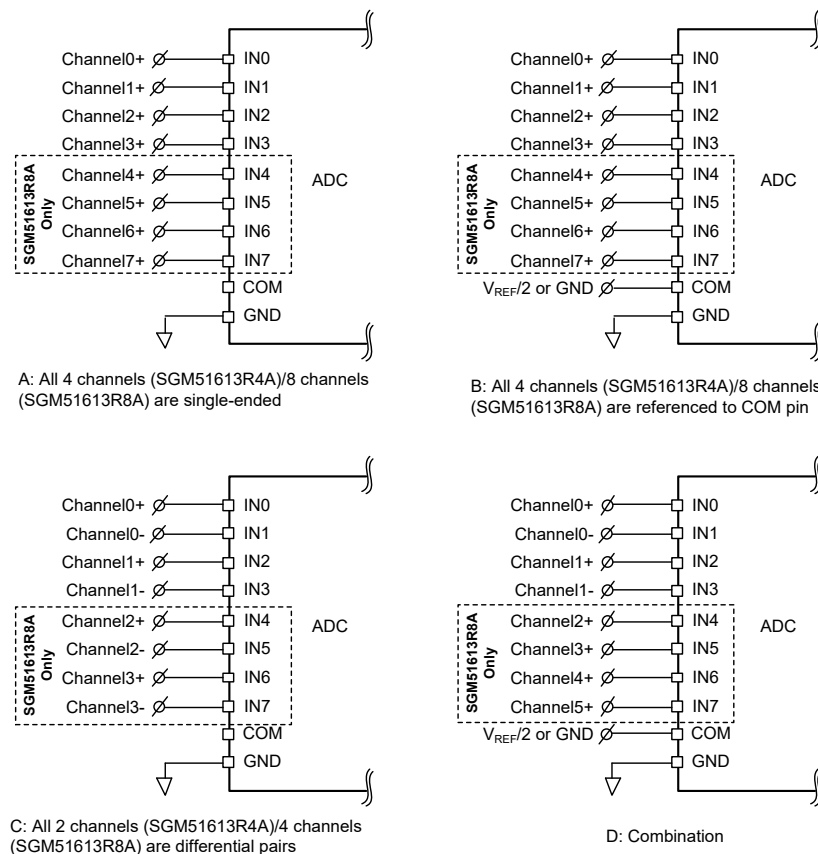
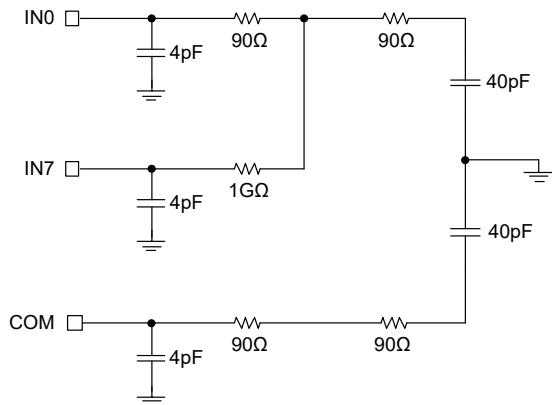


Figure 8. Multiplexed Analog Input Configurations

DETAILED DESCRIPTION (continued)



NOTE: IN0 is assumed to be on, and IN7 is assumed to be off.

Figure 9. Equivalent Analog Input Circuit

Sequencer

The SGM51613R4A and SGM51613R8A support automatic channel scanning. The channel configuration can be single-ended, pseudo differential to COM or pseudo differential paired. And the temperature sensor also can be configured into the scan sequence, if it is selected, the temperature sensor will be read after the last ADC channel.

In the single-ended mode and differential to COM mode, the scan sequence starts at IN0 and ends at the channel which is configured by CFG[9:7].

In the differential paired mode, the scan sequence starts at channel0+ (IN0) and channel0- (IN1), and ends at the paired channel set by CFG[9:7]. In the auto scan mode, the positive input is always the even INx and the negative input is always the odd INx, regardless of the setting of CFG[9:7].

The auto scan sequence is initiated by setting the CFG[2:1]. Once the configuration of CFG[13:0] is uploaded to ADC, the DIN must be held low at least 13 SCLK clocks before the next CFG[13:0] is written to ADC. During these clocks, the ADC data can be read normally.

During the scan sequence, the CFG[13:0] can be updated. Once the CFG[11] or CFG[9:7] is changed, the scan sequence will be restarted from IN0 (or paired with IN1 in pseudo differential mode).

When using the sequencer, the channel number corresponding to the conversion result can be achieved by reading back register configuration. Because the register configuration contains channel information and this information is updated in real time. In other words, the channel number is constantly updated and corresponds one-to-one with the new conversion result. For example, set the sequencer to sample channel Ch0 to Ch5 for one cycle. After reading the conversion result of Ch0, send another 14 SCLKs and read back the register configuration. Bit[9:7] of CFG must be 0. After reading the conversion result of Ch5, send another 14 SCLKs and read back the register configuration. Bit[9:7] of CFG must be 5. Additionally, if temperature data needs to be read back in sequencer mode, the temperature data will be attached at the end of codes.

Driver Amplifier Choice

To get the best performance, an input buffer amplifier is recommended. Refer to Figure 10 to Figure 13.

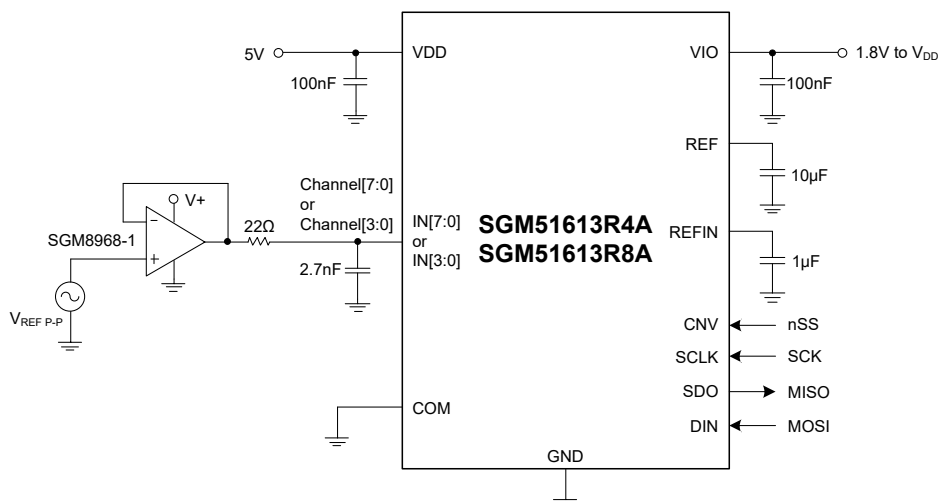


Figure 10. Typical Application with Single-Ended Input or Differential Input to a Common Reference (to GND)

DETAILED DESCRIPTION (continued)

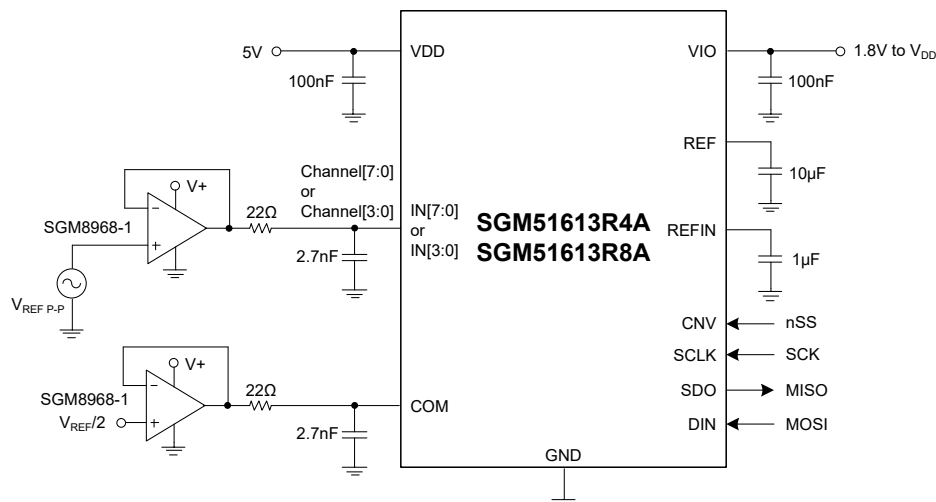


Figure 11. Typical Application with Differential Input to a Common Reference (to 1/2VREF)

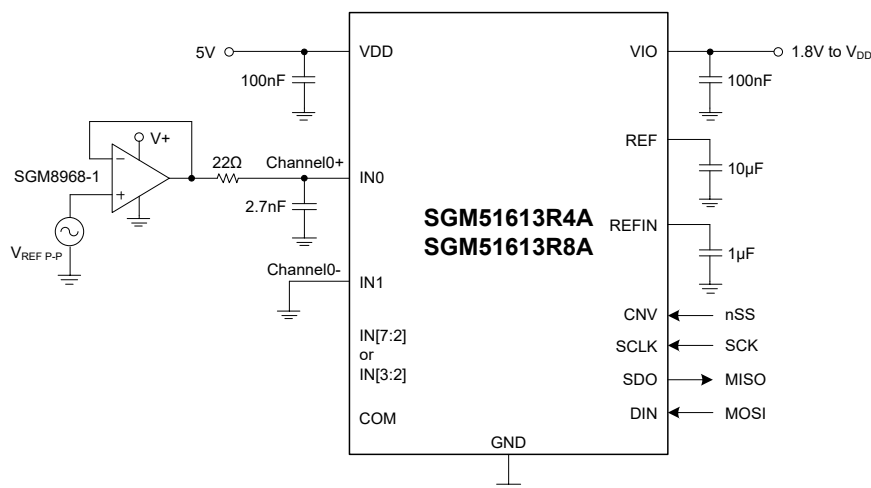


Figure 12. Typical Application with Differential Pairs Input (Reference to GND)

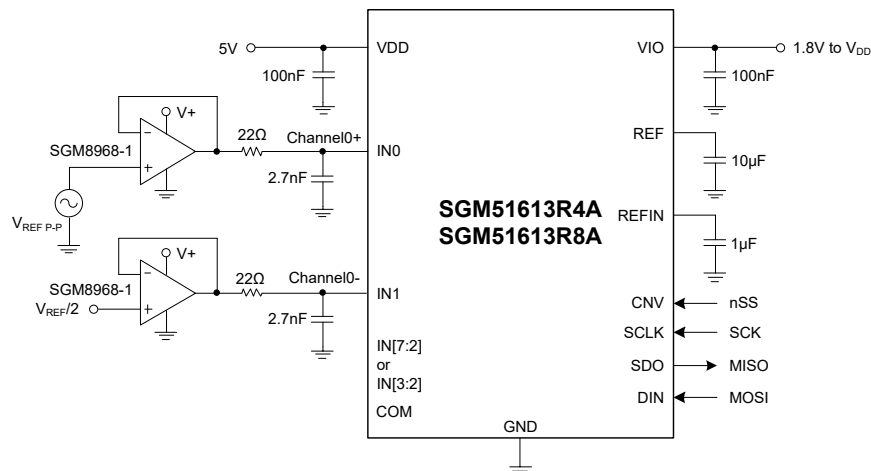


Figure 13. Typical Application with Differential Pairs Input (Reference to 1/2VREF)

DETAILED DESCRIPTION (continued)

Voltage Reference

The SGM51613R4A and SGM51613R8A have an on-chip low drift reference. The chip can work with internal reference or external reference. More details are described in Table 3 and Table 4.

If the internal reference is enabled, the voltage is output on the REFIN pin which needs a decoupling capacitor. If the voltage is used for the other circuit, a buffer amplifier is recommended.

If an external reference is used for the better system performance, it can be connected to REFIN pin or REF pin. When it is connected to VREFIN pin, the internal reference buffer must be enabled at the same time. When it is connected to REF pin, an external buffer is optional.

Temperature Sensor

To enable the internal temperature sensor, the internal reference must be active and the internal buffer enabling is not necessary at the same time.

The temperature sensor is a single-ended input to ADC and referenced to GND. Its output is straight binary.

The output code of the temperature sensor can be described as follows:

$$\text{Temperature Sensor Code} = \text{Temperature Sensor Voltage} \times (\text{Reference Voltage}) / (2^{16} - 1)$$

In which, the voltage of the temperature sensor output is typically 620mV at +25°C. The sensitivity of temperature sensor is about 2mV/°C.

Table 3. Register Content

D[13]	D[12]	D[11]	D[10]	D[9]	D[8]	D[7]	D[6]	D[5]	D[4]	D[3]	D[2]	D[1]	D[0]
CFG	INCC[2:0]			INx[2:0]			BW	REF[2:0]			SEQ[1:0]		RB

Table 4. Configuration Register Details

BITS	BIT NAME	DESCRIPTION	COMMENT
D[13]	CFG	Configuration Update 0 = Keep current configuration settings 1 = Overwrite contents of register	The read back value is always 1.
D[12:10]	INCC[2:0]	Input Channel Configuration 00X ⁽¹⁾ = Bipolar differential pairs, INx- referenced to $V_{REF}/2 \pm 0.1V$ 010 = Bipolar, INx referenced to $COM = V_{REF}/2 \pm 0.1V$ 011 = Temperature sensor 10X ⁽¹⁾ = Unipolar differential pairs, INx- referenced to $GND \pm 0.1V$ 110 = Unipolar, IN0 to IN7 (for SGM51613R8A) or IN3 (for SGM51613R4A) referenced to $COM = GND \pm 0.1V$ (GND sense) 111 = Unipolar, IN0 to IN7 (for SGM51613R8A) or IN3 (for SGM51613R4A) referenced to GND	Selection of pseudo bipolar, pseudo differential, pairs, single-ended, or temperature sensor. Refer to the Input Configurations section.
D[9:7]	INx[2:0]	Input Channel Selection in Binary Fashion for SGM51613R8A 000 = IN0 001 = IN1 010 = IN2 011 = IN3 100 = IN4 101 = IN5 110 = IN6 111 = IN7 Input Channel Selection in Binary Fashion for SGM51613R4A 000 = IN0 001 = IN1 010 = IN2 011 = IN3 1XX ⁽¹⁾ = Not supported	
D[6]	BW	Select Bandwidth for Low-Pass Filter 0 = $1/4$ of BW, uses an additional series resistor to further bandwidth limit the noise, which can improve SNR and decrease THD slightly. Maximum throughput must also be reduced to $1/4$ 1 = Full BW	Suggestion: If there are no special requirements, it is recommended to configure BW = 1.

DETAILED DESCRIPTION (continued)**Table 4. Configuration Register Details (continued)**

BITS	BIT NAME	DESCRIPTION	COMMENT
D[5:3]	REF[2:0] ⁽²⁾	Reference/Buffer Selection 000 = Do not use 001 = Internal reference and temperature sensor enabled. REF = 4.096V buffered output 010 = Use external reference. Temperature sensor enabled. Internal buffer disabled 011 = Use external reference. Internal buffer and temperature sensor enabled 100 = Do not use 101 = Do not use 110 = Use external reference. Internal reference, internal buffer and temperature sensor disabled 111 = Use external reference. Internal buffer enabled. Internal reference and temperature sensor disabled	Selection of internal, external, and external buffered references, and enabling of the on-chip temperature sensor.
D[2:1]	SEQ[1:0]	Channel Sequencer 00 = Disable sequencer 01 = Update configuration during sequence 10 = Scan IN0 to IN[7:0] (for SGM51613R8A) or IN[3:0] (for SGM51613R4A) (set in CFG[9:7]), then temperature 11 = Scan IN0 to IN[7:0] (for SGM51613R8A) or IN[3:0] (for SGM51613R4A) (set in CFG[9:7])	Allow scanning channels in an IN0 to IN[7:0] (for SGM51613R8A) or IN[3:0] (for SGM51613R4A) fashion. Refer to the Sequencer section.
D[0]	RB	Read Back the CFG Register 0 = Read back current configuration at end of data 1 = Do not read back contents of configuration	

NOTES:

1. X = Don't care.
2. When internal bandgap reference is enabled, the temperature sensor is always enabled.

REVISION HISTORY

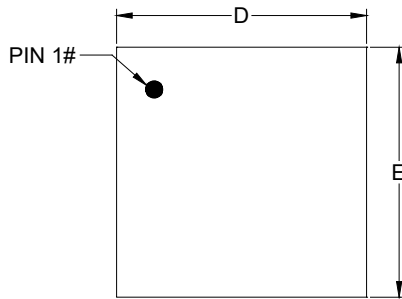
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original to REV.A (OCTOBER 2025)**Page**

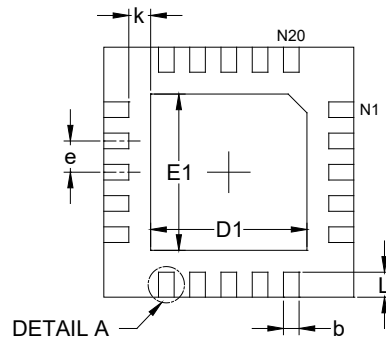
Changed from product preview to production data.....	All
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PACKAGE OUTLINE DIMENSIONS

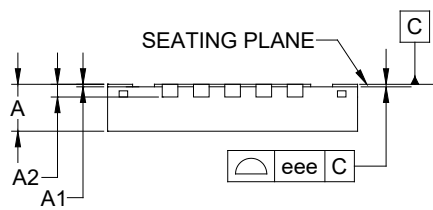
TQFN-4×4-20AL



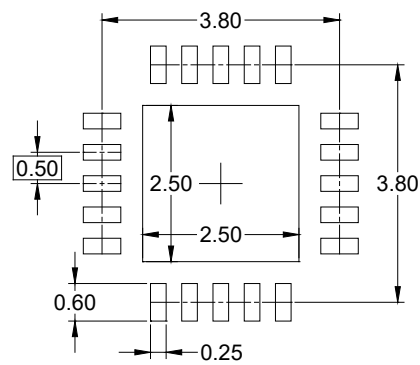
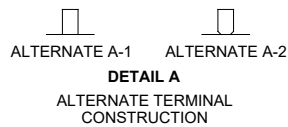
TOP VIEW



BOTTOM VIEW



SIDE VIEW



RECOMMENDED LAND PATTERN (Unit: mm)

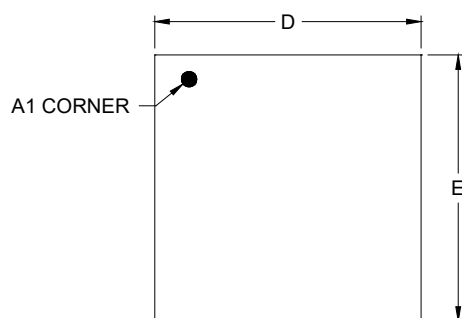
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	0.700	-	0.800
A1	0.000	-	0.050
A2	0.203 REF		
b	0.200	-	0.300
D	3.900	-	4.100
E	3.900	-	4.100
D1	2.400	-	2.600
E1	2.400	-	2.600
e	0.500 BSC		
k	0.350 REF		
L	0.300	-	0.500
eee	0.080		

NOTE: This drawing is subject to change without notice.

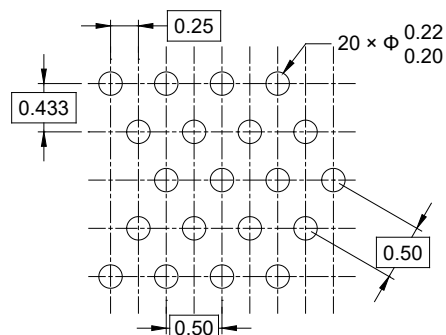
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

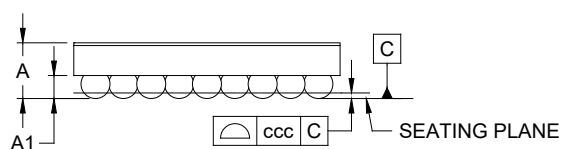
WLCSP-2.39×2.39-20B



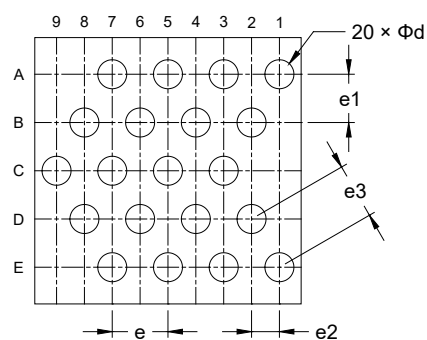
TOP VIEW



RECOMMENDED LAND PATTERN (Unit: mm)



SIDE VIEW



BOTTOM VIEW

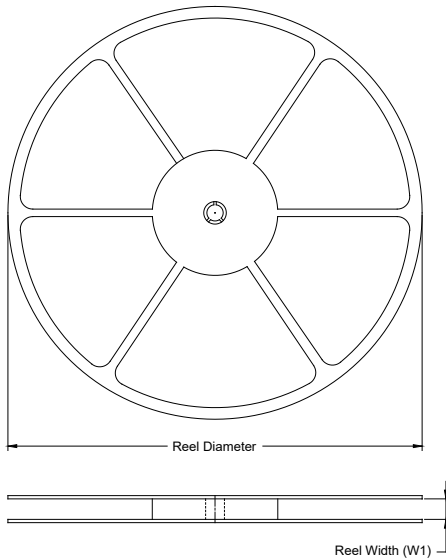
Symbol	Dimensions In Millimeters		
	MIN	NOM	MAX
A	-	-	0.538
A1	0.186	-	0.226
D	2.360	-	2.420
E	2.360	-	2.420
d	0.230	-	0.290
e	0.500 BSC		
e1	0.433 BSC		
e2	0.250 BSC		
e3	0.500 BSC		
ccc	0.050		

NOTE: This drawing is subject to change without notice.

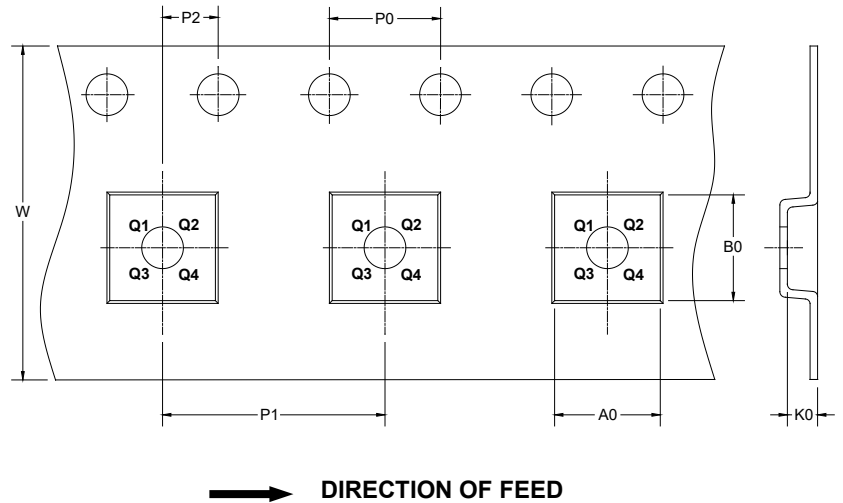
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

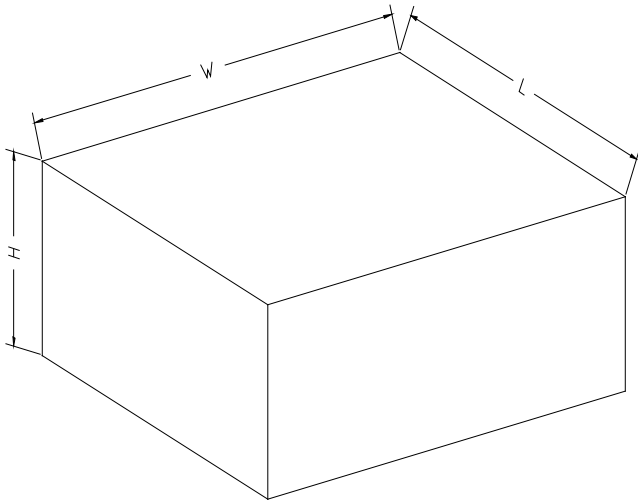
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-4×4-20AL	13"	12.4	4.30	4.30	1.10	4.0	8.0	2.0	12.0	Q2
WLCSP-2.39×2.39-20B	7"	9.5	2.52	2.52	0.75	4.0	4.0	2.0	8.0	Q1

DD00001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

DD0002